

## WIDE INPUT RANGE NON-SYNCHRONOUS VOLTAGE MODE CONTROLLER

### FEATURES

- Input Voltage Range 4.5 to 52 V
- Output Voltage (700 mV to 90%  $V_{IN}$ )
- 200 mA Internal P-Channel FET Driver
- Voltage Feed-Forward Compensation
- Undervoltage Lockout
- Programmable Fixed Frequency (35–500 kHz) Operation
- Programmable Short Circuit Protection
- Hiccup Overcurrent Fault Recovery
- Programmable Closed Loop Soft Start
- 700 mV 1% Reference Voltage
- External Synchronization
- Small 8-Pin SOIC (D) Package

### APPLICATIONS

- Industrial Control
- Distributed Power Systems
- DSL/Cable Modems
- Scanners
- Telecom

### DESCRIPTION

The TPS40200 is a flexible non-synchronous controller with a built in 200-mA driver for P-channel FETs. The circuit operates with inputs up to 52 V with a power-saving feature that turns off driver current once the external FET has been fully turned on. This feature extends the flexibility of the device, allowing it to operate with an input voltage up to 52 V without dissipating excessive power. The circuit operates with voltage-mode feedback and has feed-forward input-voltage compensation that responds instantly to input voltage change. The integral 700-mV reference is trimmed to 2%, providing the means to accurately control low voltages. The TPS40200 is available in an 8-pin SOIC, and supports many of the features of more complex controllers. Clock frequency, soft-start, and overcurrent limit are each easily programmed by a single, external component. The part has undervoltage lockout, and can be easily synchronized to other controllers or a system clock to satisfy sequencing and/or noise-reduction requirements.

Major sections in this data sheet include:

- [Specifications](#)
- [General Information](#)
- [Example Applications](#)
- [Design References](#)

### TYPICAL APPLICATION

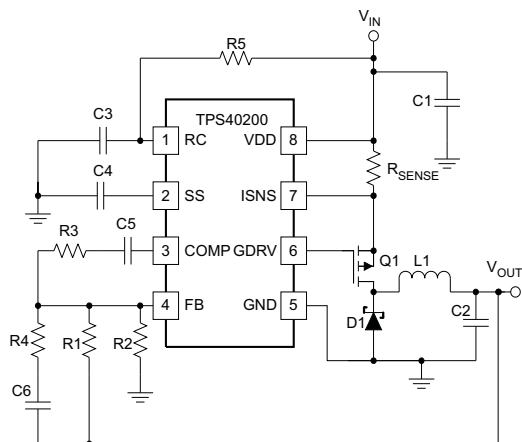


Figure 1. 12 V to 5 V Buck Converter with 94% Efficiency

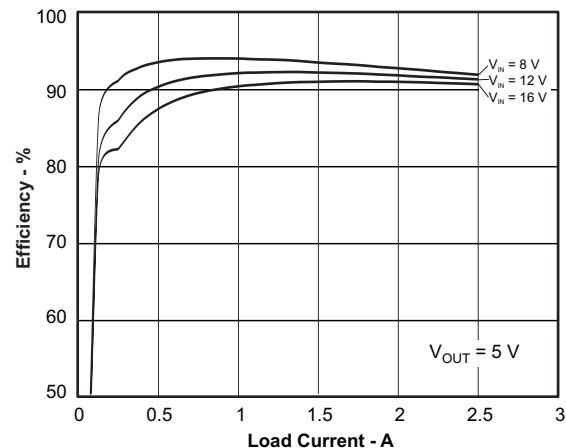


Figure 2. Typical Efficiency of Application Circuit 1 (described in [Application 1](#))



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## ELECTROSTATIC DISCHARGE (ESD) PROTECTION

	MIN	MAX	UNIT
Human body model		1500	V
CDM		1500	V

## ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)

		TPS40200	UNIT
Input voltage range	$V_{DD}$ , ISNS	52	V
	RC, FB	−0.3 to 5.5	
	SS	−0.3 to 9.0	
Output voltage range	COMP	−0.3 to 9.0	V
	GDRV	$(V_{IN} - 10)$ to $V_{IN}$	
$T_{stg}$	Storage temperature	−55 to 150	°C
	Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260	°C

## RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM	MAX	UNIT
$V_{DD}$	Input voltage	4.5	52	V
$T_A$	Operating temperature range	−40	85	°C

## ELECTRICAL CHARACTERISTICS

–40°C < T<sub>A</sub> = T<sub>J</sub> < 85°C, V<sub>DD</sub> = 12 V, f<sub>OSC</sub> = 100 kHz (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
VOLTAGE REFERENCE							
V <sub>FB</sub>	Feedback voltage	COMP = FB, T <sub>A</sub> = 25°C		689	696	702	mV
		4.5 < V <sub>DD</sub> < 52	T <sub>A</sub> = 25°C	686	696	703	
			–40°C < T <sub>A</sub> < 85°C	679	696	708	
			–40°C < T <sub>A</sub> < 125°C	679	696	710	
GATE DRIVER							
I <sub>src</sub>	Gate driver pull-up current			125	300		mA
I <sub>snk</sub>	Gate driver pull-down current			200	300		mA
V <sub>GATE</sub>	Gate driver output voltage	V <sub>GATE</sub> = (V <sub>DD</sub> – V <sub>GDRV</sub> ), for 12 < V <sub>DD</sub> < 52		6	8	10	V
QUIESCENT CURRENT							
I <sub>qq</sub>	Device quiescent current	f <sub>OSC</sub> = 300 kHz, Driver not switching, 4.5 < V <sub>DD</sub> < 52			1.5	3.0	mA
UNDERVOLTAGE LOCKOUT (UVLO)							
V <sub>UVLO(on)</sub>	Turn-on threshold	–40°C < T <sub>A</sub> < 125°C		3.8	4.25	4.5	V
V <sub>UVLO(off)</sub>	Turn-off threshold				4.05		
V <sub>UVLO(HYST)</sub>	Hysteresis			110	200	275	mV
SOFT START							
R <sub>SS(chg)</sub>	Internal Soft Start pull-up resistance			65	105	170	kΩ
R <sub>SS(dchg)</sub>	Internal Soft Start pull-down resistance			190	305	485	
V <sub>SSRST</sub>	Soft start reset threshold			100	150	200	mV
OVERCURRENT PROTECTION							
V <sub>ILIM</sub>	overcurrent threshold	4.5 < V <sub>DD</sub> < 52	0°C < T <sub>A</sub> < 125°C	65	100	140	mV
			–40°C < T <sub>A</sub> < 125°C	55	100	140	
OC <sub>DF</sub>	overcurrent duty cycle	(1)		2			%
V <sub>ILIM(rst)</sub>	overcurrent reset threshold			100	150	200	mV
OSCILLATOR							
F <sub>OSC</sub>	Oscillator frequency range	(1)		35		500	kHz
	Oscillator frequency	R <sub>RC</sub> = 200 kΩ, C <sub>RC</sub> = 470 pF		85	100	115	
		R <sub>RC</sub> = 68.1 kΩ, C <sub>RC</sub> = 470 pF		255	300	345	
Frequency line regulation		12 V < V <sub>DD</sub> < 52 V		–9		0	%
		4.5 V < V <sub>DD</sub> < 12 V		–20		0	
V <sub>RMP</sub>	Ramp amplitude	4.5 V < V <sub>DD</sub> < 52 V		VDD±10			V
PULSE WIDTH MODULATOR							
t <sub>MIN</sub>	Minimum controllable pulse width. See Figure 25 for for t <sub>MIN</sub> vs f <sub>OSC</sub> at various input voltages.	V <sub>DD</sub> = 12 V			200	400	ns
		V <sub>DD</sub> = 30 V			100	200	
D <sub>MAX</sub>	Maximum duty cycle	F <sub>OSC</sub> = 100 kHz, C <sub>L</sub> = 470 pF		93	95		%
		F <sub>OSC</sub> = 300 kHz, C <sub>L</sub> = 470 pF		90	93		
K <sub>PWM</sub>	Modulator and power stage DC gain			8	10	12	V/V
ERROR AMPLIFIER							
I <sub>IB</sub>	Input bias current				100	250	nA
AOL	Open loop gain	(1)		60	80		dB
GBWP	Unity gain bandwidth	(1)		1.5	3		MHz
I <sub>COMP(src)</sub>	Output source current	V <sub>FB</sub> = 0.6 V, COMP = 1 V		100	250		μA

(1) By design only. Not tested in production.

## ELECTRICAL CHARACTERISTICS (continued)

$-40^{\circ}\text{C} < T_A = T_J < 85^{\circ}\text{C}$ ,  $V_{DD} = 12\text{ V}$ ,  $f_{OSC} = 100\text{ kHz}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$I_{COMP(snk)}$ Output sink current	$V_{FB} = 1.2\text{ V}$ , $COMP = 1\text{ V}$	1.0	2.5		mA

## THERMAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$\theta_{JC}$ Thermal resistance, Junction to Case	(1)		49		$^{\circ}\text{C}/\text{Watt}$

- (1) TI uses test boards designed to JESD 51-3 and JESD 51-7 for thermal-impedance measurements. The parameters outlined in these standards also are used to set up thermal models. TI uses the thermal-model program ThermCAL, a finite-difference thermal-modeling tool. Using this test procedure, the junction-to-case thermal resistance of this part is  $49^{\circ}\text{C}/\text{W}$ .

## ORDERING INFORMATION

$T_A$	OUTPUT VOLTAGE	PACKAGE	PART NUMBER	MEDIUM	QUANTITY
$-40^{\circ}\text{C}$ to $85^{\circ}\text{C}$	Adjustable	Plastic Small-Outline (D)	TPS40200D	Tape and reel	2500/Reel <sup>(1)</sup>

- (1) Add an R suffix to the device type to order 2500 devices per reel

## DEVICE INFORMATION

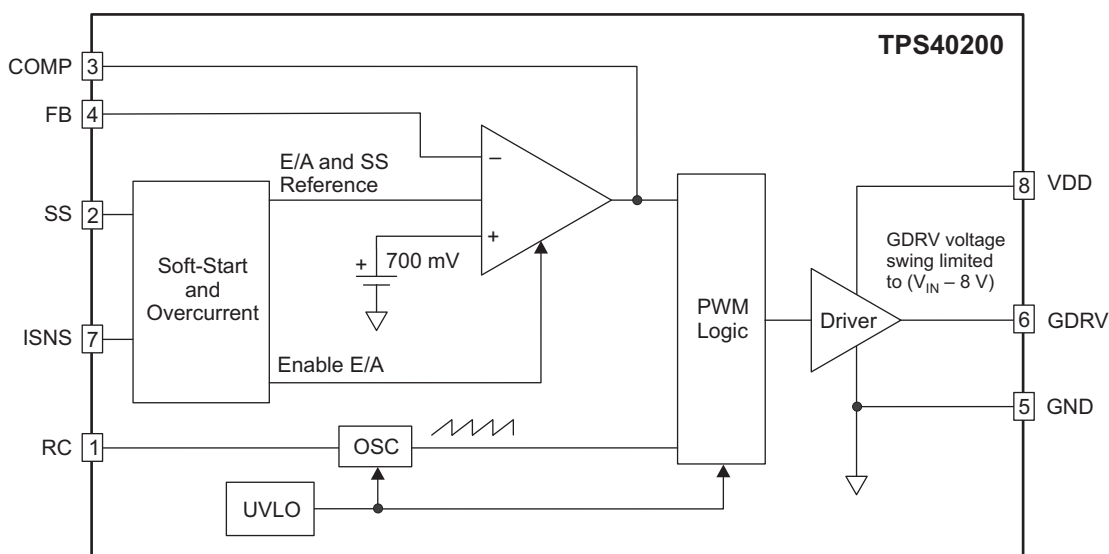


Figure 3. Functional Block Diagram

D PACKAGE (TOP VIEW)

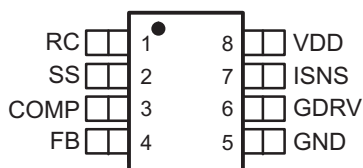
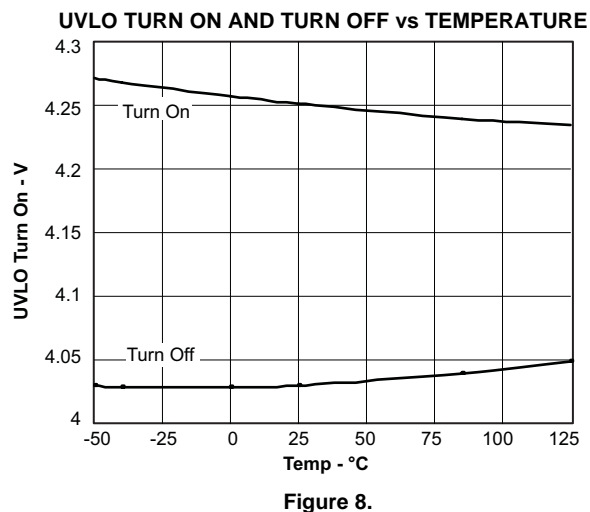
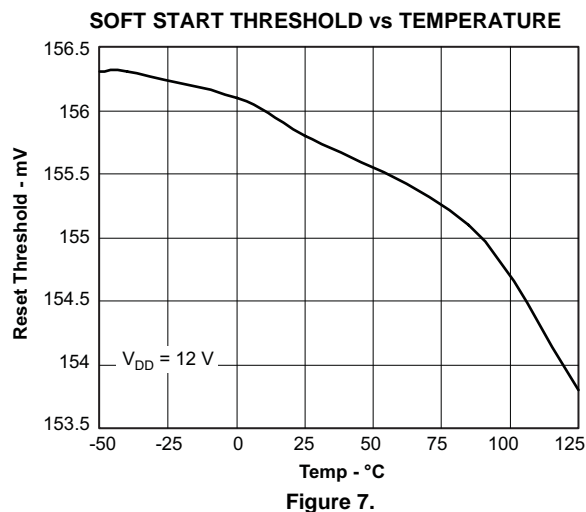
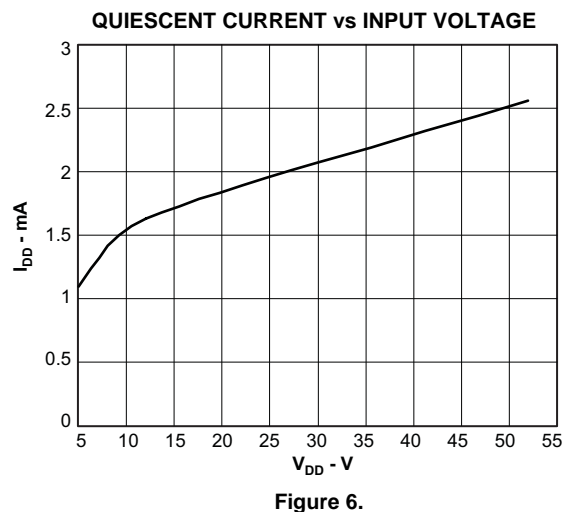
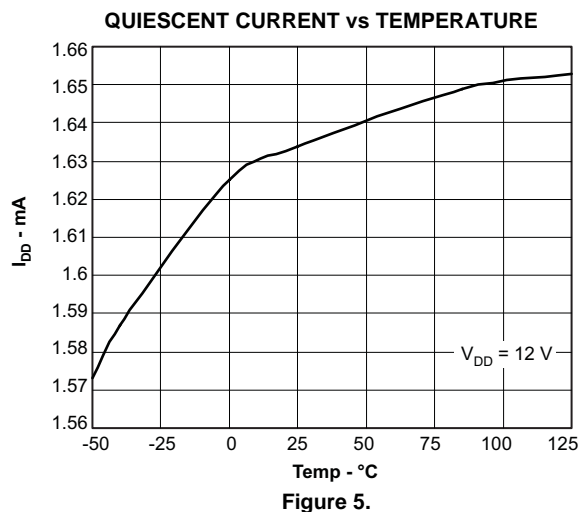


Figure 4. Device Pinout

**Table 1. TERMINAL FUNCTIONS**

TERMINAL NAME	NO.	I/O	DESCRIPTION
RC	1	I	Switching frequency setting RC network. Connect capacitor from RC pin to GND pin and resistor from $V_{IN}$ pin to RC pin. The device may be synchronized to an external clock by connecting an open drain output to this pin and pulling it to GND. The pulse width for synchronization should not be excessive. See <a href="#">Section 2</a> .
SS	2	I	Soft-start programming pin. Connect capacitor from SS to GND to program soft start time. Pulling this pin below 150 mV causes the output switching to stop, placing the device in a shutdown state. The pin also functions as a restart timer for overcurrent events.
COMP	3	O	Error amplifier output. Connect control loop compensation network from COMP to FB.
FB	4	I	Error amplifier inverting input. Connect feedback resistor network center tap to this pin.
GND	5		Device ground.
GDRV	6	O	Driver output for external P-channel MOSFET
ISNS	7	I	Current-sense comparator input. Connect a current sense resistor between ISNS and $V_{DD}$ in order to set desired overcurrent threshold.
VDD	8	I	System input voltage. Connect local bypass capacitor from $V_{DD}$ to GND.

## TYPICAL CHARACTERISTICS



## TYPICAL CHARACTERISTICS (continued)

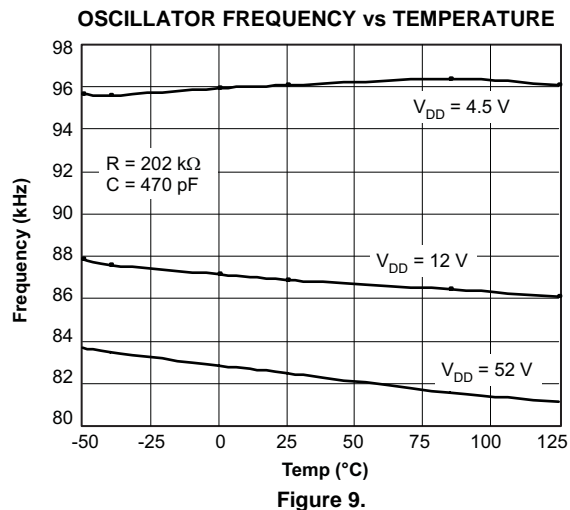


Figure 9.

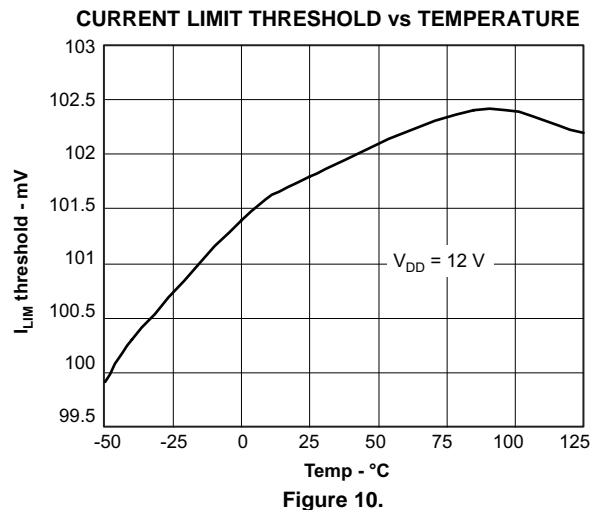


Figure 10.

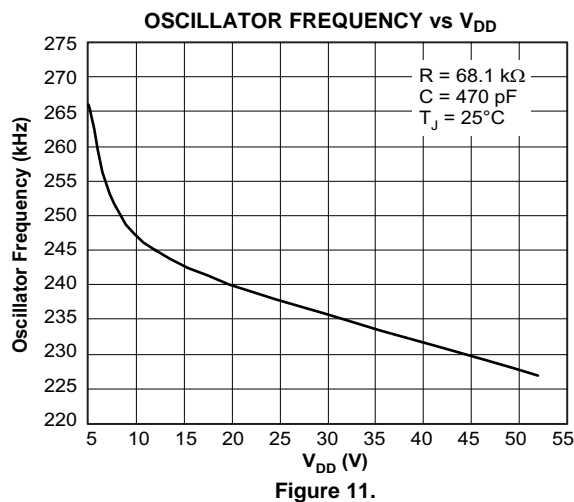


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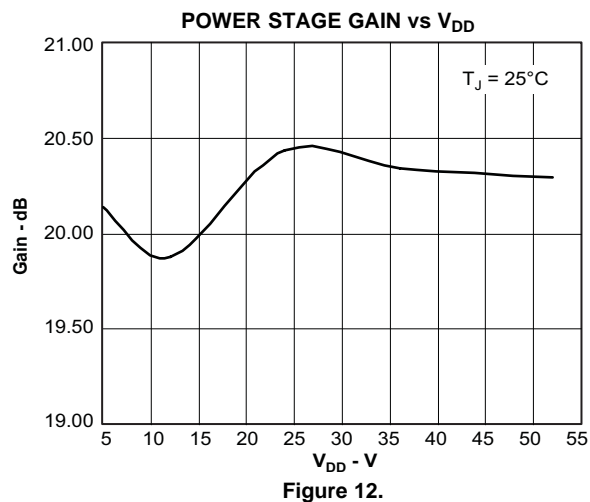


Figure 12.

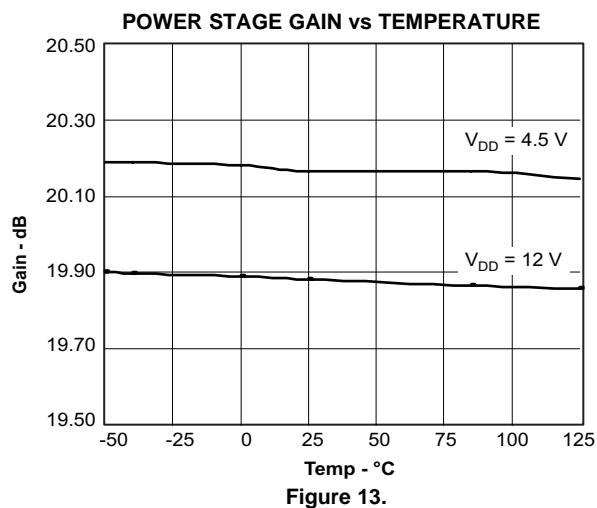


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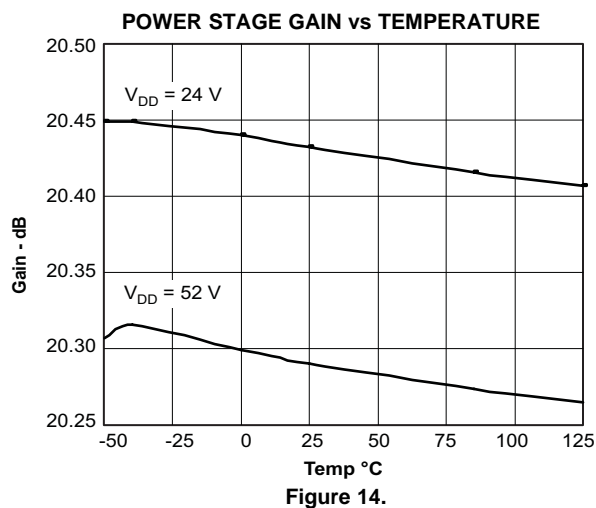


Figure 14.

## TYPICAL CHARACTERISTICS (continued)

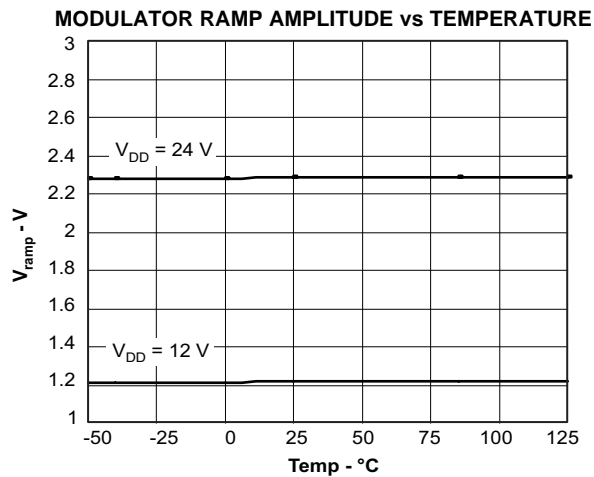


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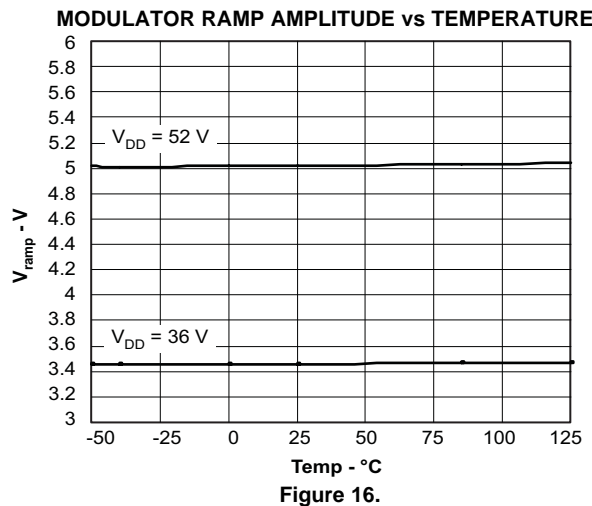


Figure 16.

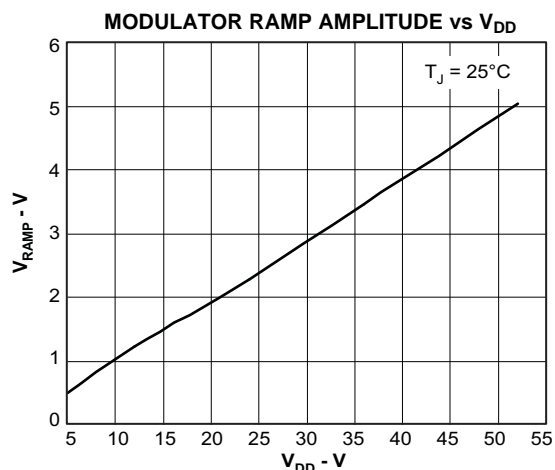


Figure 17.

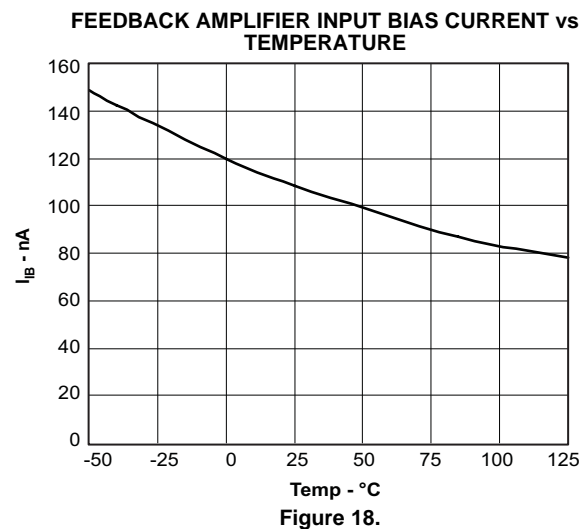


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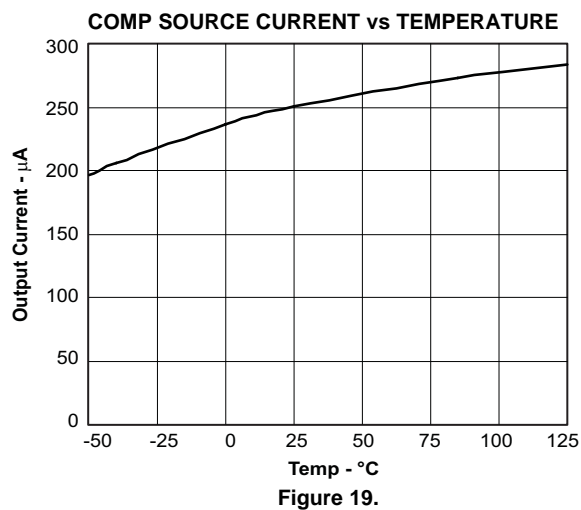


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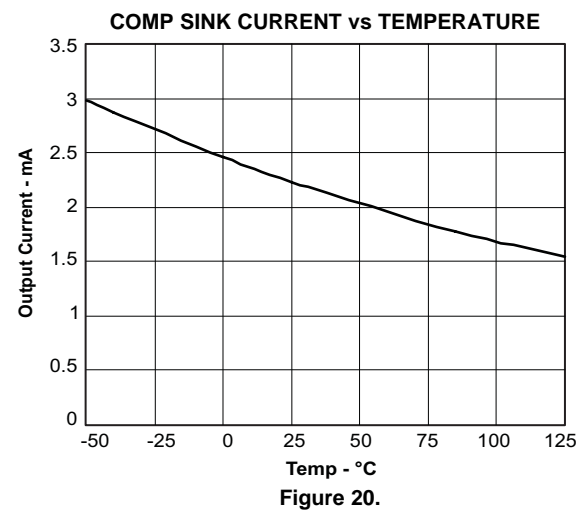


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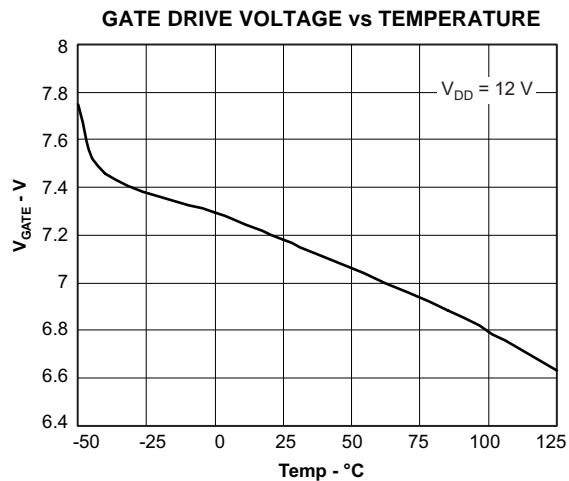
**TYPICAL CHARACTERISTICS (continued)**

Figure 21.

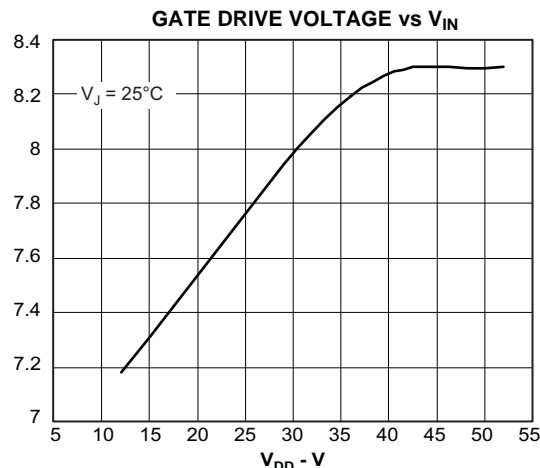


Figure 22.

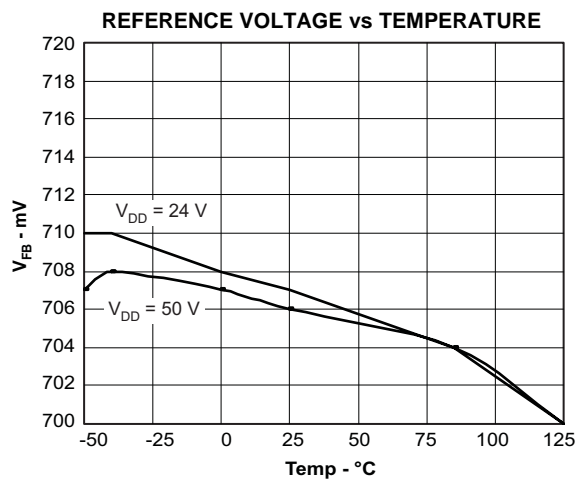


Figure 23.

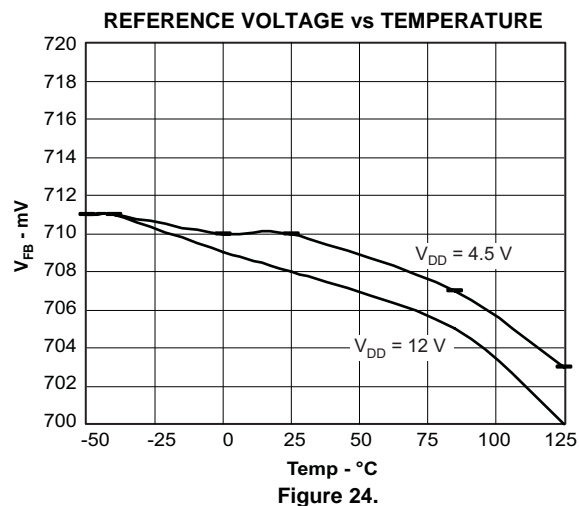


Figure 24.

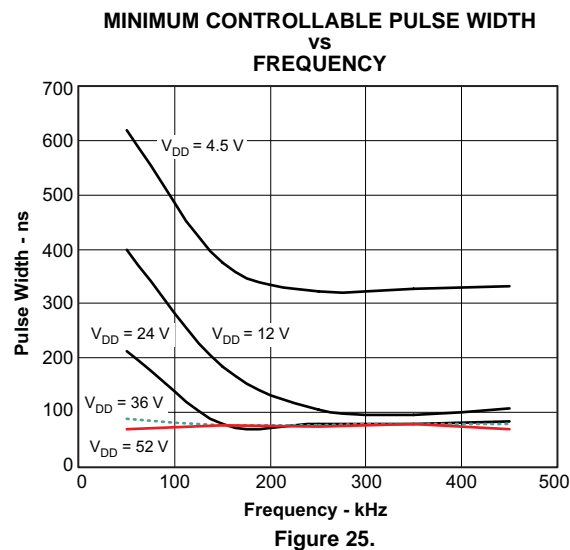


Figure 25.



## GENERAL INFORMATION

### Overview

The TPS40200 is a non-synchronous controller with a built in 200-mA driver designed to drive high speed P-channel FETS up to 500 kHz. Small size combined with complete functionality makes the part both versatile and easy to use.

The controller uses a low-value current-sensing resistor in series with the input voltage and the power FET's source connection to detect switching current. When the voltage drop across this resistor exceeds 100 mV, the part enters a hiccup fault mode at about 2% of the operating frequency.

The device uses voltage feedback to an error amplifier that is biased by a precision 700-mV reference. Feed-forward compensation from the input keeps the PWM gain constant over the full input voltage range, eliminating the need to change frequency compensation for different input voltages.

The part also incorporates a soft-start feature where the output follows a slowly rising soft-start voltage, preventing output-voltage overshoot.

### Programming the Operating Frequency

The operating frequency of the controller is determined by an external resistor  $R_{RC}$  that is connected from the RC pin to VDD and a capacitor attached from the RC pin to ground. This connection and the two oscillator comparators inside the device, are shown in [Figure 26](#). The oscillator frequency can be calculated from the following equation:

$$f_{SW} = \frac{1}{R_{RC} \times C_{RC} \times 0.105}$$

Where :

- $f_{SW}$  is the clock frequency
- $R_{RC}$  is the timing resistor value in  $\Omega$
- $C_{RC}$  is the timing capacitor value in F

$R_{RC}$  must be kept large enough that the current through it does not exceed 750  $\mu$ A when the internal switch (shown in [Figure 26](#)) is discharging the timing capacitor. This condition may be expressed by [Equation 1](#).

$$\frac{V_{IN}}{R_{RC}} \leq 750 \mu A \quad (1)$$

### Synchronizing the Oscillator

[Figure 26](#) shows the functional diagram of the oscillator. When synchronizing the oscillator to an external clock, the RC pin must be pulled below 150 mV for 20 ns or more. The external clock frequency must be higher than the free running frequency of the converter as well. When synchronizing the controller, if the RC pin is held low for an excessive amount of time, erratic operation may occur. The maximum amount of time that the RC pin should be held low is 50% of a nominal output pulse, or 10% of the period of the synchronization frequency.

Under circumstances where the input voltage is high and the duty cycle is less than 50%, a Schottky diode connected from the RC pin to an external clock may be used to synchronize the oscillator. The cathode of the diode is connected to the RC pin. The trip point of the oscillator is set by an internal voltage divider to be 1/10 of the input voltage. The clock signal must have an amplitude higher than this trip point. When the clock goes low, it allows the reset current to restart the RC ramp, synchronizing the oscillator to the external clock. This provides a simple, single-component method for clock synchronization.

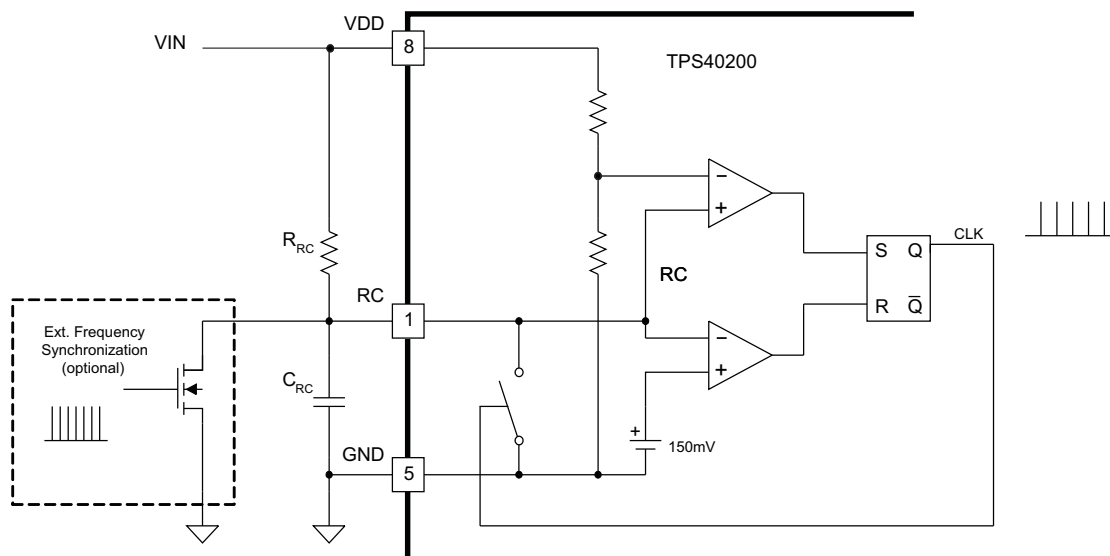


Figure 26. Oscillator Functional Diagram

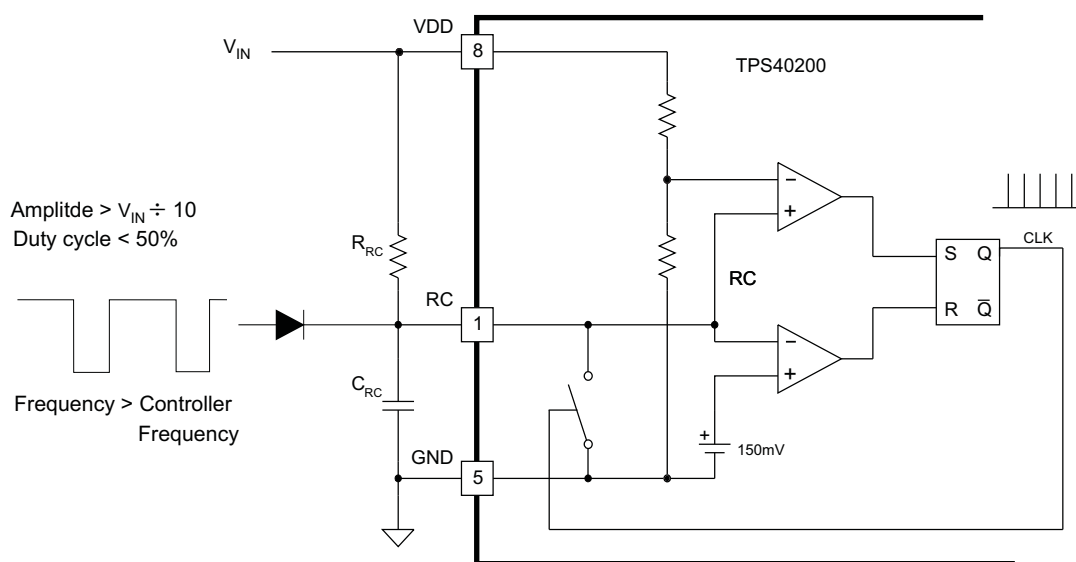


Figure 27. Diode Connected Synchronization

## Current Limit Resistor Selection

As shown in Figure 30, a resistor in series with the power MOSFET sets the overcurrent protection level. Use a low-inductance resistor to avoid ringing signals and nuisance tripping. When the FET is on and the controller senses 100mV or more drop from the VDD pin to the ISNS pin, an overcurrent condition is declared. When this happens, the FET is turned off, and as shown in Figure 29, the soft-start capacitor is discharged. When the soft-start capacitor reaches a level below 150 mV, the converter clears the overcurrent condition flag and attempts to restart. If the condition that caused the overcurrent event to occur is still present on the output of the converter (see Figure 28), another overcurrent condition is declared and the process repeats indefinitely. Figure 28 shows the soft start capacitor voltage during an extended output fault condition. The overall duty cycle of current conduction during a persistent fault is approximately 2%.

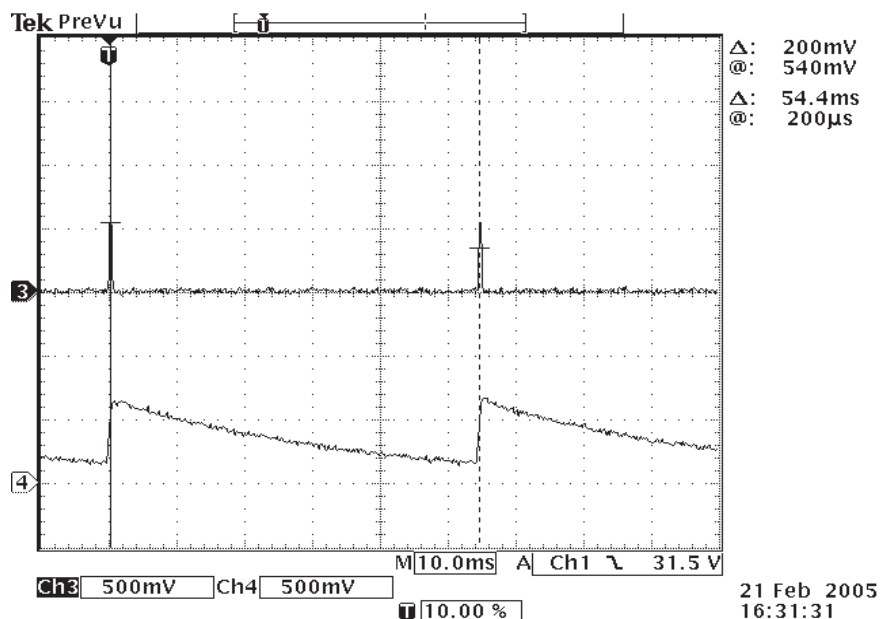


Figure 28. Typical Soft-Start Capacitor and V<sub>OUT</sub> During Overcurrent

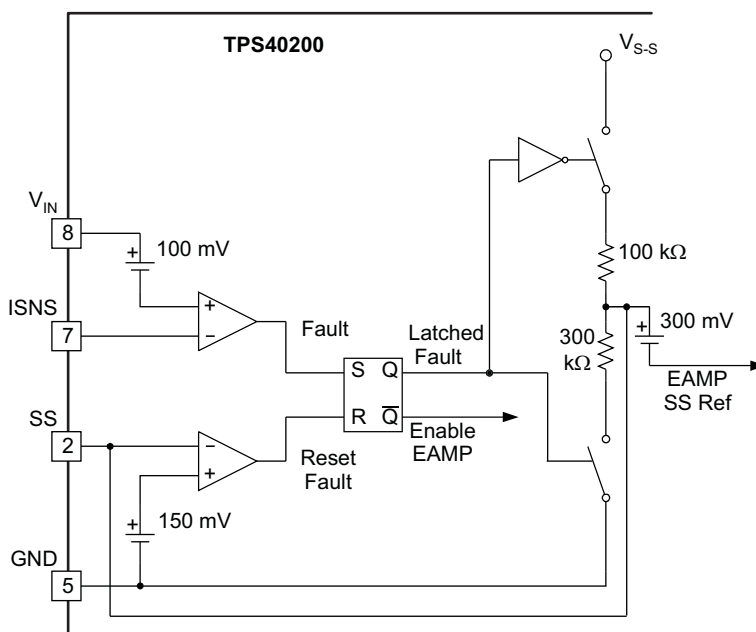


Figure 29. Current Limit Reset

If necessary, a small R-C filter can be added to the current sensing network to reduce nuisance tripping due to noise pickup. This filter can also be used to trim the overcurrent trip point to a higher level with the addition of a single resistor. See Figure 30. The nominal overcurrent trip point using the circuit of Figure 30 is described as:

$$I_{OC} = \frac{V_{ILIM}}{R_{ILIM}} \times \frac{R_{F1} + R_{F2}}{R_{F2}}$$

where

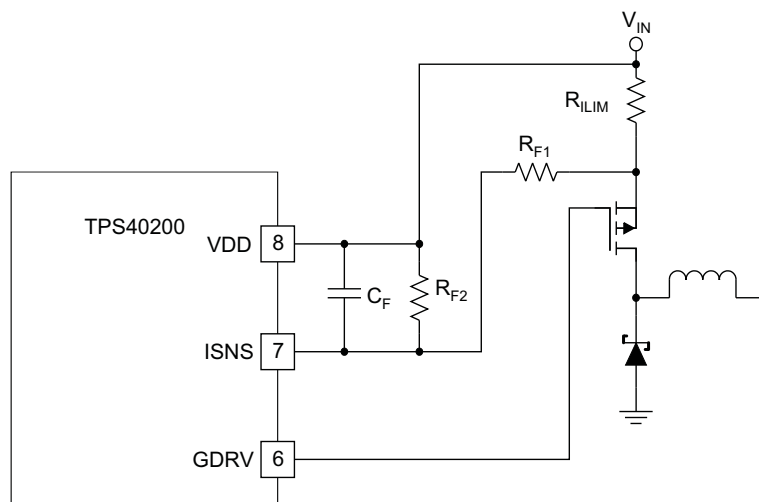
- $I_{OC}$  is the overcurrent trip point, peak current in the inductor
- $V_{ILIM}$  is the overcurrent threshold voltage for the TPS40200, typically 100 mV
- $R_{ILIM}$  is the value of the current sense resistor in  $\Omega$
- $R_{F1}$  and  $R_{F2}$  are the values of the scaling resistors in  $\Omega$

The value of the capacitor is determined by the nominal pulse width of the converter and the values of the scaling resistors  $R_{F1}$  and  $R_{F2}$ . It is best not to have the time constant of the filter longer than the nominal pulse width of the converter, otherwise a substantial increase in the overcurrent trip point occurs. Using this constraint, the capacitor value may be bounded by the following:

$$C_f \leq \frac{V_O}{V_{IN} \times f_{SW}} \div \frac{R_{f1} \times R_{f2}}{R_{f1} + R_{f2}}$$

Where:

- $C_f$  is the value of the current limit filter capacitor in F
- $V_O$  is the output voltage of the converter
- $V_{IN}$  is the input voltage to the converter
- $f_{SW}$  is the converter switching frequency
- $R_{f1}$  and  $R_{f2}$  are the values of the scaling resistors in  $\Omega$



NOTE: The current limit resistor and its associated circuitry can be eliminated and pins 7 and 8 shorted. The result of this however, may result in damage to the part or PC board in the event of an overcurrent event.

**Figure 30. Current Limit Adjustment**

## MOSFET Gate Drive

The output driver sinking current is approximately 200 mA, and is designed to drive P-channel power FETs. When the driver pulls the gate charge of the FET it is controlling to  $-8$  V, the drive current folds back to a low level so that high-power dissipation only occurs during the turn-on period of the FET. This feature is particularly valuable when turning on a FET at high input voltages where leaving the gate drive current on would otherwise cause unacceptable power dissipation.

## Undervoltage Lockout Protection

Undervoltage lockout (UVLO) protection ensures proper startup of the device only when the input voltage has exceeded minimum operating voltage. Undervoltage protection incorporates hysteresis which eliminates hiccup starting in cases where input supply impedance is high.

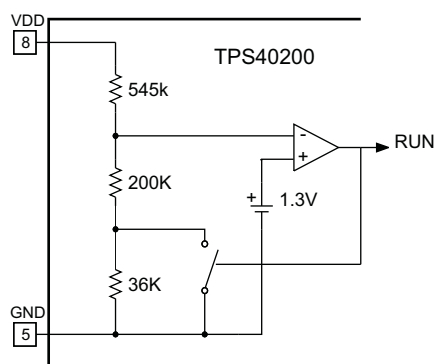


Figure 31. Undervoltage Lockout

Undervoltage protection ensures proper startup of the device only when the input voltage has exceeded minimum operating voltage. The UVLO level is measured at the VDD pin with respect to GND. Startup voltage is typically 4.3 V with approximately 200 mV of hysteresis. The device shuts off at a nominal 4.1 V. As shown in Figure 31, when the input  $V_{DD}$  voltage rises to 4.3 V, the 1.3 V comparator's threshold voltage is exceeded and a RUN signal occurs. Feedback from the output closes the switch, and shunts the 200 k $\Omega$  resistor so that an approximately 200-mV lower voltage, or 4.1 V, is required before the part shuts down.

## Programming the Soft-Start Time

An external capacitor  $C_{SS}$ , connected from the SS pin to ground controls the soft-start interval. An internal charging resistor connected to  $V_{DD}$  produces a rising reference voltage which is connected through a 700-mV offset to the reference input of the TPS40200 error amplifier. When the soft-start capacitor voltage ( $V_{CSS}$ ) is below 150 mV, there is no switching activity. When  $V_{CSS}$  rises above the 700-mV offset, the error amplifier starts to follow  $V_{SST}-700$  mV, and uses this rising voltage as a reference. When  $V_{CSS}$  reaches 1.4 V, the internal reference takes over, and further increases have no effect. An advantage of initiating a slow start in this fashion is that the controller cannot overshoot because its output follows a scaled version of the controller reference voltage. A conceptual drawing of the circuit that produces these results is shown in Figure 32. A consequence of the 700 mV offset is that the controller does not start switching until the  $V_{CSS}$  has charged up to 700 mV. The output remains at 0 V during the resulting delay. When  $V_{CSS}$  exceeds the 700-mV offset, the TPS40200 output follows the soft-start time constant. Once above 1.4 V, the 700-mV internal reference takes over, and normal operation begins.

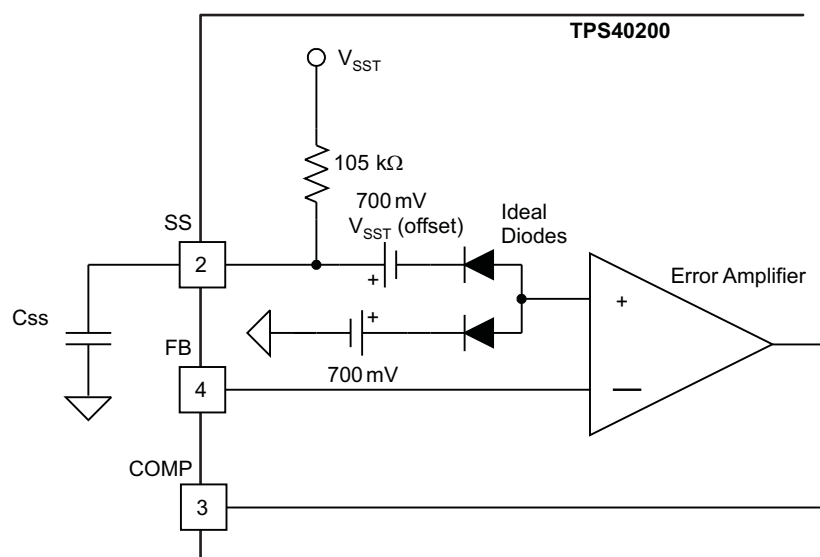


Figure 32. Soft-Start Circuit

The slow-start time should be more (slower) than the time constant of the output LC filter. This time constraint may be expressed as:

$$t_s \geq 2\pi \times \sqrt{L_O \times C_O} \quad (2)$$

The calculation of the soft start interval is simply the time it takes the RC network to exponentially charge from 0 V to 1.4 V. An internal 105-kΩ charging resistor is connected from the SS pin to  $V_{SST}$ . For applications where the voltage is above 8 V, an internal regulator clamps the maximum charging voltage to 8 V.

The result of this is a formula for the start up time, as given by:

$$t_{SS} = R_c \times C_{SS} \times \ln \left( \frac{V_{SST}}{V_{SST} - 1.4} \right)$$

where

- $t_{SS}$  is the required soft-start time in seconds
- $C_{SS}$  is the soft-start capacitor value in F
- $R_c$  is the internal soft-start charging resistor (105 kΩ nominal)
- $V_{SST}$  is the input voltage up to a maximum of 8 V

## Voltage Setting and Modulator Gain

Since the input current to the error amplifier is negligible, the feedback impedance can be selected over a wide range. Knowing that the reference voltage is 708 mV, pick a convenient value for R1 and then calculate the value of R2 from Equation 1.

$$V_{OUT} = 0.708 \left( 1 + \frac{R_2}{R_1} \right) \quad (3)$$

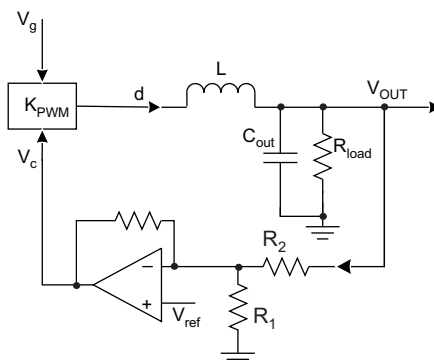


Figure 33. System Gain Elements

The error amplifier has a DC open loop gain of at least 60 dB with a minimum of a 1.5-MHz Gain Bandwidth Product which gives the user flexibility with respect to the type of feedback compensation he uses for his particular application. The gain selected by the user at the crossover frequency is set to provide an over all unity gain for the system. The crossover frequency should be selected so that the error amplifier open-loop gain is high with respect to the required closed-loop gain, ensuring that the amplifier response is determined by the passive feedback elements.

## EXAMPLE APPLICATIONS

### Application 1: Buck Regulator, 8-to-12 V Input, 3.3 V or 5.0 V at 2.5 A Output

#### Overview

The buck regulator design shown in Figure 34 shows the use of the TPS40200. It delivers 2.5 A at either 3.3 V or 5.0 V as selected by a single feedback resistor. It achieves approximately 90 % efficiency at 3.3 V and 94% at 5.0 V. A discussion of design tradeoffs and methodology is included to serve as a guide to the successful design of forward converters using the TPS40200.

The List of Materials for this application is given in Table 3. The efficiency and load regulation from boards built from this design are shown in Figure 35 and Figure 36. Gerber files and additional application information are available from the factory.

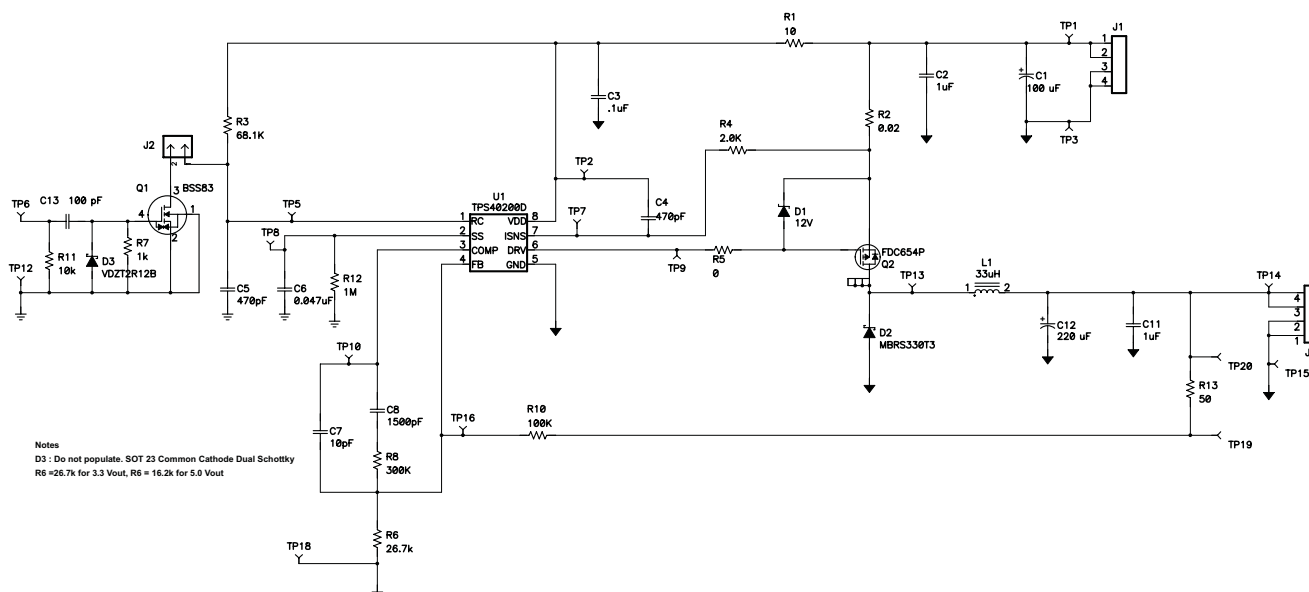


Figure 34. 8-to-16 V<sub>IN</sub> Step-Down Buck Converter

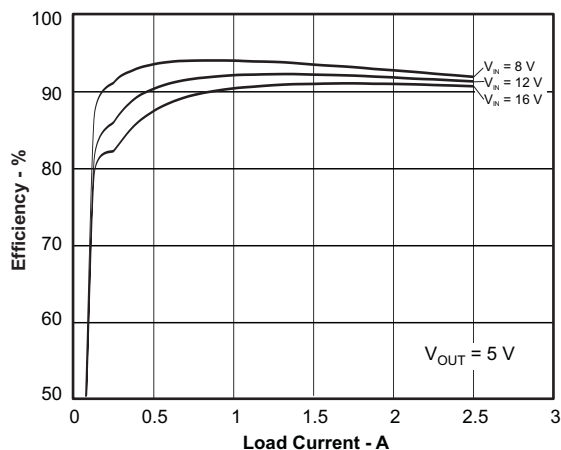


Figure 35. Full-Load Efficiency at 5.0 V<sub>OUT</sub>

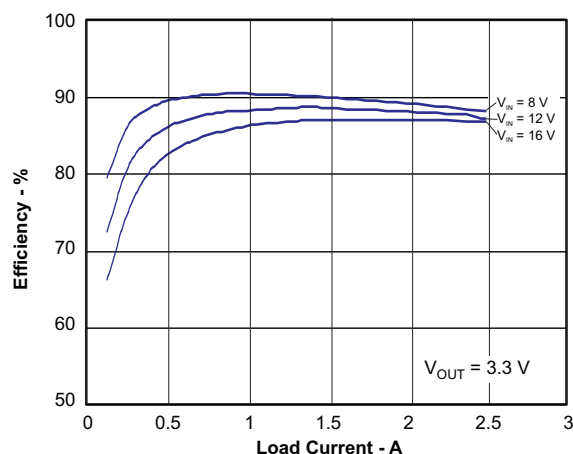


Figure 36. Full-Load Efficiency at 3.3 V<sub>OUT</sub>



## Component Selection

**Table 2. Design Parameters**

Symbol	Parameter	Test Condition	MIN	NOM	MAX	UNIT
V <sub>IN</sub>	Input Voltage		8.0	12	16.0	V
V <sub>OUT</sub>	Output Voltage	I <sub>OUT</sub> at 2.5A	3.200	3.3	3.400 <sup>(1)</sup>	V
	Line Regulation	.2 % V <sub>OUT</sub>	3.293	3.3	3.307	V
	Load Regulation	.2% V <sub>OUT</sub>	3.293	3.3	3.307	V
V <sub>OUT</sub>	Output Voltage	I <sub>OUT</sub> at 2.5 A	4.85	5.0	5.150 <sup>(1)</sup>	V
	Line Regulation	.2% V <sub>OUT</sub>	4.990	5.0	5.010	V
	Load Regulation	.2% V <sub>OUT</sub>	4.990	5.0	5.010	V
V <sub>RIPPLE</sub>	Output ripple voltage	At maximum output current		60		mV
V <sub>OVER</sub>	Output overshoot	For 2.5 A load transient from 2.5 A to 0.25 A		100		mV
V <sub>UNDER</sub>	Output undershoot	For 2.5 A load transient from 0.25 A to 2.5 A		60		mV
I <sub>OUT</sub>	Output Current		0.125		2.5	A
I <sub>SCP</sub>	Short circuit current trip point		3.75		5.00	A
	Efficiency	At nominal input voltage and maximum output current		90		%
F <sub>S</sub>	Switching frequency			300		kHz

(1) Set point accuracy is dependent on external resistor tolerance and the IC reference voltage. Line and Load regulation values are referenced to the nominal design output voltage.

### FET Selection Criteria

1. The maximum input voltage for this application is 16 V. Switching the inductor causes overshoot voltages that can equal the input voltage. Since the R<sub>DS(on)</sub> of the FET rises with breakdown voltage, select a FET with as low a breakdown voltage as possible. In this case, a 30-V FET was selected.
2. The selection of a power FET size requires knowing both the switching losses and DC Losses in the application. AC losses are all frequency dependent and directly related to device capacitances and device size. On the other hand, DC losses are inversely related to device size. The result is an optimum where the two types of losses are equal. Since device size is proportional to R<sub>DS(on)</sub>, begin by selecting a device with an R<sub>DS(on)</sub> that results in a small loss of power relative to package thermal capability and overall efficiency objectives.
3. In this application, the efficiency target is 90% and the output power 8.25 W. This gives a total power-loss budget of 0.916 W. Total FET losses must be small relative to this number.

The DC conduction loss in the FET is given by:  $P_{DC} = I_{rms}^2 \times R_{DS(on)}$

The rms current is given by:

$$I_{rms} = \left[ D \times \left( I_{OUT}^2 + \frac{\Delta I_{pp}^2}{12} \right) \right]^{\frac{1}{2}}$$

where

- $\Delta I_{pp} = \Delta V \times D \times \frac{t_s}{L_i}$
- $\Delta V = V_{IN} - V_{OUT} - (DCR + R_{DS(on)}) \times I_{OUT}$
- R<sub>DS(on)</sub> is the FET on-state resistance
- DCR is the the inductor DC resistance
- D is the duty cycle
- t<sub>s</sub> = the reciprocal of the switching frequency

Using the values in this example, the dc power loss is 129 mW. The remaining FET losses are as follows:

- $P_{SW}$  is the power dissipated while switching the FET on and off
- $P_{gate}$  is the power dissipated driving the FET gate capacitance
- $P_{COSS}$  is the power switching the FET output capacitance

The total power dissipated by the FET is the sum of these contributions.

$$P_{FET} = P_{SW} + P_{gate} + P_{COSS} + P_{RDSON}$$

The P-channel FET used in this application is a FDC654P with the following characteristics:

$$\begin{aligned} t_{rise} &= 13 \times 10^{-9} & C_{OSS} &= 83 \times 10^{-12} \\ t_{fall} &= 6 \times 10^{-9} & Q_g &= 9 \text{ nC} \\ R_{DSON} &= 0.1 \, \Omega & V_{gate} &= 1.9 \text{ V} \\ Q_{gd} &= 1.2 \times 10^{-9} & Q_{gs} &= 1.0 \times 10^{-9} \end{aligned}$$

Using these device characteristics and the following formulas we get:

$$P_{SW} = \frac{f_S}{2} \times \left( V_{IN} \times I_{pk} \times t_{CHON} \right) + \frac{f_S}{2} \left( V_{IN} \times I_{pk} \times t_{CHOFF} \right) = 10 \text{ mW}$$

$$\text{Where } t_{CHON} = \frac{Q_{GD} \times R_G}{V_{IN} - V_{TH}} \text{ and } t_{CHOFF} = \frac{Q_{GD} \times R_G}{V_{IN}} \text{ are the switching times for the power FET.}$$

$$P_{GATE} = Q_G \times V_{GATE} \times f_S = 22 \text{ mW} \quad (4)$$

$$P_{COSS} = \frac{C_{OSS} \times V_{IN\_MAX}^2 \times f_S}{2} = 2 \text{ mW} \quad (5)$$

$$I_G = Q_G \times f_S = 2.7 \text{ mA is the gate current.}$$

The sum of the switching losses is 34 mW, and is comparable to the 129 mW DC losses. At added expense, a slightly larger FET is better because the DC loss drops and the AC losses increase, with both moving toward the optimum point of equal losses.

## Rectifier Selection Criteria

### 1. Rectifier Breakdown Voltage

The rectifier has to withstand the maximum input voltage which in this case is 16 V. To allow for switching transients which can approach the switching voltage a 30 V rectifier was selected.

### 2. Diode Size

The importance of power losses from the Schottky rectifier D2 is determined by the duty cycle. For a low duty cycle application, the rectifier is conducting most of the time, and the current that flows through it times its forward drop can be the largest component of loss in the entire controller. In this application, the duty cycle ranges from 20% to 40%, which in the worst case means that the diode is conducting 80% of the time. Where efficiency is of paramount importance, choose a diode with a minimum of forward drop. In more cost sensitive applications, size may be reduced to the point of the thermal limitations of the diode package.

The device in this application is large relative to the current required by the application. In a more cost sensitive application, a smaller diode in a less-expensive package will provide a less-efficient but appropriate solution

The device used has the following characteristics:

- $V_f = 0.3$  V at 3 A
- $C_t = 300$  pF ( $C_t$  = the effective reverse voltage capacitance of the synchronous rectifier, D2.)

The two components of the losses from the diode D2 are:

$$P_{COND} = V_f \times \left( I_{OUT} + \frac{I_{RIPPLE}}{4} \right) \times (1 - D) = 653 \text{ mW}$$

Where:

- D = the duty cycle
- $I_{RIPPLE}$  is the ripple current
- $I_{OUT}$  is the output current
- $V_f$  is the forward voltage
- $P_{COND}$  is the conduction power loss

The switching capacitance of this diode adds an AC loss, given by:

$$P_{SW} = \frac{1}{2} \left[ C \times (V_{IN} + V_f)^2 \times f \right] = 6.8 \text{ mW}$$

This additional loss raises the total loss to: 660 mW (7)

At an output voltage of 3.3 V, the application runs at a nominal duty cycle of 27%, and the diode is conducting 72.5% of the time. As the output voltage is moved up to 5 V, the on-time increases to 46% and the diode is conducting only 54% of the time during each clock cycle. This change in duty cycle proportionately reduces the conduction power losses in the diode. This reduction may be expressed as

$$660 \left( \frac{0.54}{0.725} \right) = 491 \text{ mW}$$

for a savings in power of 660 - 491 = 169 mW.

To illustrate the relevance of this power savings we measured the full load module Efficiency for this application at 3.3 and 5 V. The 5 volt output efficiency is 92% vs. 89% for the 3.3-V design. This difference in efficiency represents a 456-mW reduction in losses between the two conditions. This 169-mW power-loss reduction in the rectifier represents 37% of the difference.

## Inductor Selection Criteria

The P-channel FET driver facilitates switching the power FET at a high frequency. This, in turn, enables the use of smaller, less-expensive inductors as illustrated in this 300-kHz application. Ferrite, with its good high frequency properties, is the material of choice. Several manufacturers provide catalogs with inductor saturation currents, inductance values, and LSR's (internal resistance) for their various-sized ferrites.

In this application, the device must deliver a maximum current of 2.5 A. This requires that the output inductor's saturation current be above 2.5 A plus the ripple current caused during inductor switching. The value of the inductor determines this ripple current. A low value of inductance has a higher ripple current that contributes to ripple voltage across the resistance of the output capacitors. The advantages of a low inductance are a higher transient response, lower DCR, a higher saturation current, and a smaller, less expensive part. Too low an inductor however, leads to higher peak currents which ultimately are bounded by the overcurrent limit set to protect the output FET or by output ripple voltage. Fortunately, with low ESR Ceramic capacitors on the output, the resulting ripple voltage for relatively high ripple currents can be small.

For example, a single 1-μf, 1206 size, 6.3-V, ceramic capacitor has an internal resistance of 2 Ω at 1 MHz. For this 2.5 A application, a 10% ripple current of 0.25 A produces a 50-mV ripple voltage. This ripple voltage may be further reduced by additional parallel capacitors.

The other bound on inductance is the minimum current at which the controller enters discontinuous conduction. At this point, Inductor current is zero. The minimum output current for this application is specified at 0.125 A. This average current is the peak current that must develop during a minimum on time. The conditions for minimum on time are high line and low load.

Using:

$$L_{\text{MIN}} = \frac{V_{\text{IN}} - V_{\text{OUT}}}{I_{\text{PEAK}}} \times t_{\text{ON}} = 32 \mu\text{H}$$

where

- $V_{\text{IN}} = 16 \text{ V}$
- $V_{\text{OUT}} = 3.3 \text{ V}$
- $I_{\text{PEAK}} = 0.25 \text{ A}$
- $t_{\text{ON}} = 0.686 \mu\text{s}$
- $t_{\text{ON}}$  is given by  $\frac{1}{300 \text{ kHz}} \times \frac{3.3 \text{ V}}{16 \text{ V}}$

Where:

The inductor used in the circuit is the closest standard value of 33 μH. This is the minimum inductance that can be used in the converter to deliver the minimum current while maintaining continuous conduction.

## Output Capacitance

In order to satisfy the output voltage over and under shoot specifications there must be enough output capacitance to keep the output voltage within the specified voltage limits during load current steps.

In a situation where a full load of 2.5 A within the specified voltage limits is suddenly removed, the output capacitor must absorb energy stored in the output inductor. This condition may be described by realizing that the energy in the stored in the inductor must be suddenly absorbed by the output capacitance. This energy relationship is written as:

$$\frac{1}{2} \times L_O I_O^2 \leq \frac{1}{2} \times [C_O (V_{OS}^2 - V_O^2)]$$

where

- $V_{OS}$  is the allowed over-shoot voltage above the output voltage
- $L_O$  is the inductance
- $I_O$  is the output current
- $C_O$  is the output capacitance
- $V_O$  is the output voltage

In this application, the worst case load step is 2.25 A and the allowed overshoot is 100 mV. With a 33- $\mu$ H output inductor, this implies an output capacitance of 249  $\mu$ F for a 3.3-V output and 165  $\mu$ F for a 5-V output..

When the load increases from minimum to full load the output capacitor must deliver current to the load. The worst case is for a minimum on time that occurs at 16 V in and 3.3  $V_{OUT}$  and minimum load. This corresponds to an off time of  $(1 - 0.2)$  times the period 3.3- $\mu$ s and is the worst case time before the inductor can start supplying current. This situation may be represented by

$$\Delta V_O < \Delta I_O \times \frac{t_{OFFMAX}}{C_O}$$

where

- $\Delta V_O$  is the undershoot specification of 60 mV
- $\Delta I_O$  is the load current step
- $t_{OFF(max)}$  is the maximum off time

This condition produces a requirement of 100  $\mu$ F for the output capacitance. The larger of these two requirements becomes the minimum value of output capacitance.

The ripple current develops a voltage across the ESR of the output capacitance, so another requirement on this component is it ESR be small relative to the ripple voltage specification.

## Switching Frequency

The TPS40200 has a built in, 8-V, 200 mA, P-channel FET driver output that facilitates using P-channel switching FETs. A clock frequency of 300 kHz is chosen as a switching frequency that represents a compromise between a high-frequency that allows the use of smaller capacitors and inductors but one that is not so high as to cause excessive transistor switching losses. As previously discussed, an optimum frequency can be selected by picking a value where the DC and switching losses are equal.

The frequency is set by using the design formula given in the [FET Selection Criteria](#) section.

$$R_{RC} \times C_{RC} = \frac{1}{0.105 \times f_{SW}}$$

Where:

- $R_{RC}$  is the timing resistor value in  $\Omega$
- $R_{RC} = 68.1 \Omega$
- $C_{RC}$  is the timing capacitor value in F
- $C5 = 470 \text{ pF}$
- $f_{SW}$  is the desired switching frequency in Hz
- $f_{SW} = 297 \text{ kHz}$ .

At a worst case of 16 V, the timing resistor draws about 250  $\mu$ A which is well below the 750  $\mu$ A maximum which the circuit can pull down.

## Programming the Overcurrent Threshold Level

The current limit in the TSP40200 is triggered by a comparator with a 100-mV offset whose inputs are connected across a current-sense resistor between  $V_{CC}$  and the source of the high-side switching FET. When current in this resistor develops more than 100 mV, the comparator trips and terminates the output gate drive.

In this application, the current-limit resistor is set by the peak output stage current which consists of the maximum load current plus the ripple current. In this case, we have  $2.5 + 0.125 = 2.625$  A. To accommodate tolerances a 25% margin is added giving a 3.25 A peak current. Using the equation below then yields a value for  $R_{ILIM}$  of 0.30  $\Omega$ .

Current sensing in a switching environment requires attention to both circuit board traces and noise pick up. In the design shown a small RC filter has been added to the circuit to prevent switching noise from tripping the current sense comparator. The requirements of this filter are board-dependent, but with the layout used in this application, no unreasonable overcurrent is observed.

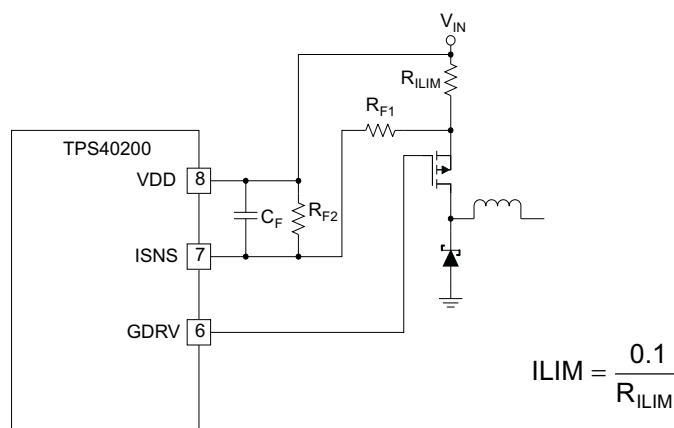


Figure 37. Overcurrent Trip Circuit for  $R_{F2}$  Open

## Soft Start Capacitor

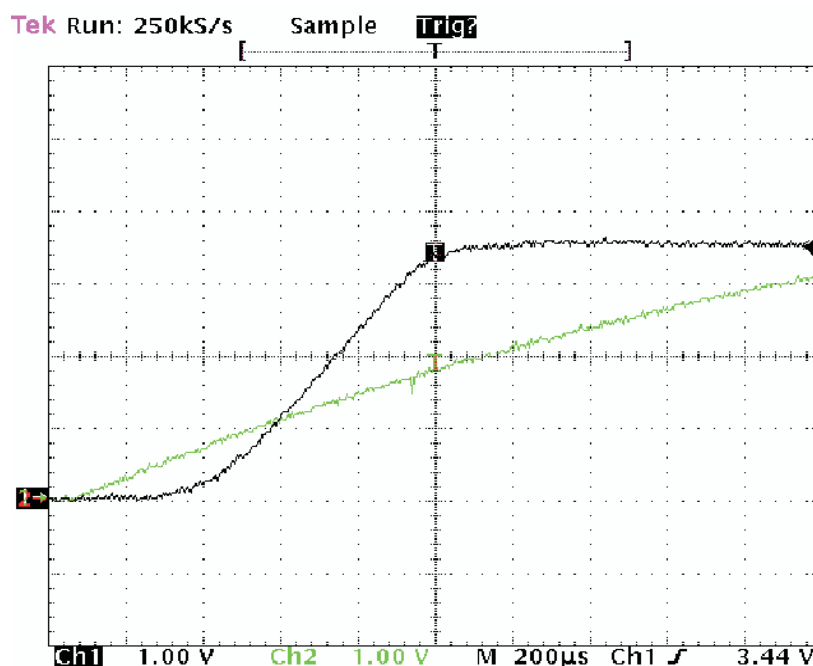
The soft start interval is given (in pF) by the following equation:

$$C_{SS} = \frac{t_{ss}}{R \times \ln\left(\frac{V_{SST}}{V_{SST} - 1.4}\right)} \times 10^3$$

where

- R is an internal 105-kΩ charging resistor
- $V_{CC}$  is the input voltage up to 8 V where the charging voltage is internally clamped to 8 V maximum
- $V_{OS} = 700$  mV, and because the input voltage is 12 V,  $V_{SST} = 8$  V.

The oscilloscope picture below shows the expected delay at the output (middle trace) until the soft-start node (bottom trace) reaches 700 mV. At this point, the output rises following the exponential rise of the soft-start capacitor voltage until the soft-start capacitor reaches 1.4 V and the internal 700-mV reference takes over. This total time is approximately 1 ms, which agrees with the calculated value of 0.95 ms where the soft start capacitance is 0.047 μF.



- Channel 1 is the output voltage ( $V_{OUT}$ ) rising to 3.3 V
- Channel 2 is the soft start pin (SS)

**Figure 38. Soft Start Showing Output Delay and Controlled Rise To Programmed Output Voltage**

## Frequency Compensation

The four elements that determine the system overall response are discussed below. The gain of the error amplifier ( $K_{EA}$ ) is the first of these elements. Its output develops a control voltage which is the input to the PWM.

The TPS40200 has a unique modulator that scales the peak to peak amplitude of the PWM ramp to be 0.1 times the value of the input voltage. Since modulator gain is given by  $V_{IN}$  divided by  $V_{RAMP}$ , the modulator gain is 10 and is constant at 10 (20 dB) over the entire specified input voltage range.

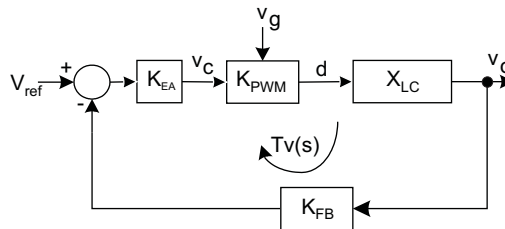
The last two elements that affect system gain are the transfer characteristic of the output LC filter and the feedback network from the output to the input to the error amplifier.

These four elements may be expressed by the following expression that represents the system transfer function as shown in [Figure 39](#).

$$T_V(s) = K_{FB} \times K_{EA}(s) \times K_{PWM} \times X_{LC}(s)$$

Where:

- $K_{FB}$  is the output voltage setting divider
- $K_{EA}$  is the error amplifier feedback
- $K_{PWM}$  is the modulator gain
- $X_{LC}$  is the filter transfer function



**Figure 39. Control Loop**



Figure 40 shows the feedback network used in this application. This is a Type II compensation network which gives a combination of good transient response and phase boost for good stability. This type of compensation has a pole at the origin causing a -20dB/decade (-1) slope followed by a zero that causes a region of flat gain followed by a final pole that returns the gain slope to -1. The bode plot in Figure 41 shows the effect of these poles and zeros.

The procedure for setting up the compensation network is as follows:

1. Determine the break frequency of the output capacitor.
2. Select a zero frequency well below this break frequency.
3. From the gain bandwidth of the error amplifier select a cross over frequency where the amplifier gain is large relative to expected closed loop gain
4. Select a second zero well above the crossover frequency, that returns the gain slope to a -1 slope.
5. Calculate the required gain for the amplifier at crossover.

Be prepared to iterate this procedure to optimize the pole and zero locations as needed.

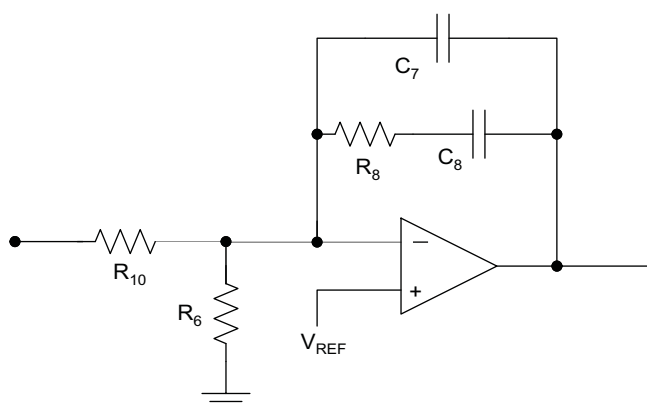


Figure 40. Error Amplifier feedback Elements

The frequency response of this converter is largely determined by two poles that arise from the LC output filter and a higher frequency zero caused by the ESR of the output capacitance. The poles from the output filter cause a 40 dB/decade roll off with a phase shift approaching 180 degrees followed by the output capacitor zero that reduced the roll off to -20 dB and gives a phase boost back toward 90 degrees. In other nomenclature, this is a -2 slope followed by a -1 slope. The two zeros in the compensation network act to cancel the double pole from the output filter. The compensation network's two poles produce a region where the error amplifier is flat and can be set to a gain such that the overall gain of the system is zero dB. This region is set so that it brackets the system crossover frequency.

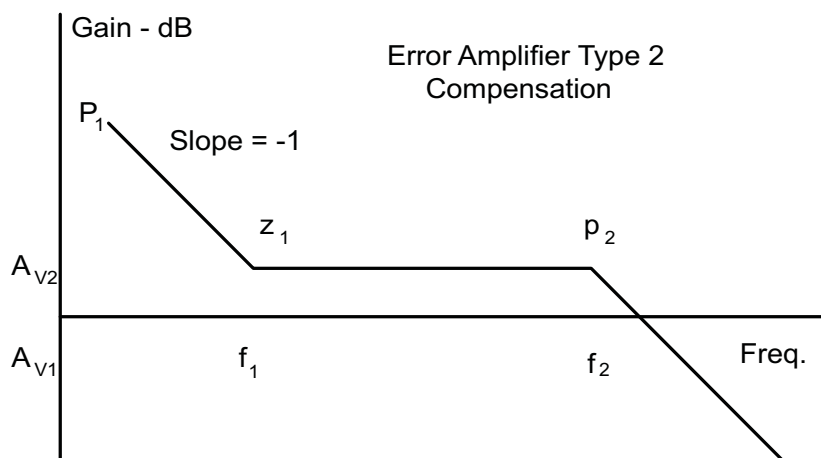


Figure 41. Error Amplifier Bode Plot

In order to properly compensate this system, it is necessary to know the frequencies of its poles and zeros.

### Step 1

The break frequency of the output capacitor is given by:

$$F_{\text{esr}} = \frac{1}{2\pi R_{\text{esr}} C}$$

where

- C = the output capacitor, 221  $\mu\text{F}$
- $R_{\text{ESR}}$  = the ESR of the capacitors

Because of the ESR of the output capacitor, the output LC filter has a single-pole response above the 1.8-kHz break frequency of the output capacitor and its ESR. This simplifies compensation since the system becomes essentially a single pole system.

### Step 2

The first zero is placed well below the 1.8-kHz break frequency of the output capacitor and its ESR. The phase boost from this zero is shown in [Figure 43](#).

$$f_{Z1} = \frac{1}{2\pi R_8 C_8}$$

where:

- $R_8 = 300 \text{ k}\Omega$
- $C_8 = 1500 \text{ pF}$
- $F_{Z1} = 354 \text{ Hz}$

### Step 3

From its minimum gain bandwidth product of 1.5 MHz, and knowing it has a 20 dB/decade roll off, the open-loop gain of the error amplifier is 33 dB at 35 kHz. This approximate frequency is chosen for a crossover frequency to keep the amplifier gain contribution to the overall system gain small, as well as following the convention of placing the crossover frequency between 1/6 to 1/10 the 300 kHz switching frequency.

### Step 4

The second pole is placed well above the 35 kHz crossover frequency.

$$f_{P2} = \frac{1}{2\pi \times C_7 \times C_8 \times R_8} \times (C_7 + C_8)$$

where

- $R_8 = 300 \text{ k}\Omega$
- $C_7 = 10 \text{ pF}$
- $C_8 = 1500 \text{ pF}$
- $f_{P2} = 53 \text{ kHz}$

### Step 5

Calculate the gain elements in the system to determine the gain required by the error amplifier to make the overall gain 0 dB at 35 kHz.

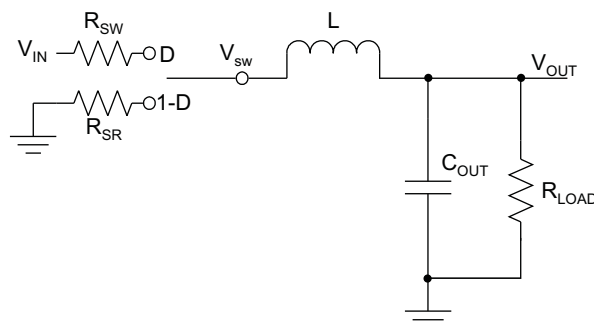
The total gain around the voltage feedback loop is:

$$T_V(s) = K_{FB} \times K_{EA}(s) \times K_{PWM} \times X_{LC}(s)$$

where

- $K_{FB}$  is the output voltage setting divider
- $K_{EA}$  is the error amplifier feedback
- $K_{PWM}$  is the modulator gain
- $X_{LC}$  is the filter transfer function

With reference to the graphic below, the output filter's transfer characteristic  $X_{LC}(s)$  can be estimated by the following:



**Figure 42. Output Filter Analysis**

$$X_{LC}(s) = \frac{Z_{OUT}(s)}{Z_{OUT}(s) + Z_L(s) + R_{SW} \times D + R_{SR} \times (1-D)}$$

where

- $Z_{OUT}$  is the parallel combination of output capacitor(s) and the load
- $R_{SW}$  is the  $R_{DS(on)}$  of the switching FET plus the current-sense resistor
- $R_{SR}$  is the resistance of the synchronous rectifier
- $D$  is the duty cycle estimated as  $3.3 / 12 = 0.27$

To evaluate  $X_{LC}(s)$  at 35 kHz use the following:

- $Z_{OUT}(s)$  at 35 kHz, which is dominated by the output capacitor's ESR; estimated to be 400 mΩ
- $Z_L(s)$  at 35 kHz is 7.25 Ω
- $R_{SW} = 0.95$  mΩ, including the  $R_{LIM}$  resistance
- $R_{SR} = 100$  mΩ

Using these numbers,  $X_{LC}(s) = 0.04$  or -27.9 db.

The feedback network has a gain to the error amplifier given by:

$$K_{fb} = \frac{R_{10}}{R_6}$$

where for 3.3 V<sub>OUT</sub>,  $R_6 = 26.7$  kΩ

Using the values in this application,  $K_{fb} = 11.4$  dB.

The modulator has a gain of 10 that is flat to well beyond 35 kHz, so  $K_{PWM} = 20$  dB.

To achieve 0 db overall gain, the amplifier and feedback gain must be set to 7.9 db (20 db – 27.9db)

The amplifier gain, including the feedback gain,  $K_{fb}$ , can be approximated by this expression:

$$\frac{V_{OUT}}{V_{IN}}(S) = \frac{A_{VOL}}{1 + \frac{R_{10}}{R_8} + \frac{R_{10}}{Z_{FS}} \times (1 + A_{VOL})}$$

Where

- $Z_{FS}$  is the parallel combination of  $C_7$  in parallel with the sum of  $R_8$  and the impedance of  $C_8$ .
- $A_{VOL}$  is the open-loop gain of the error amplifier at 35 kHz, which is 44.6, or 33 db.

Figure 43 shows the result of the compensation. The crossover frequency is 35 kHz and the phase margin is 45 degrees. The response of the system is dominated by the ESR of the output capacitor and is exploited to produce an essentially single-pole system with simple compensation.

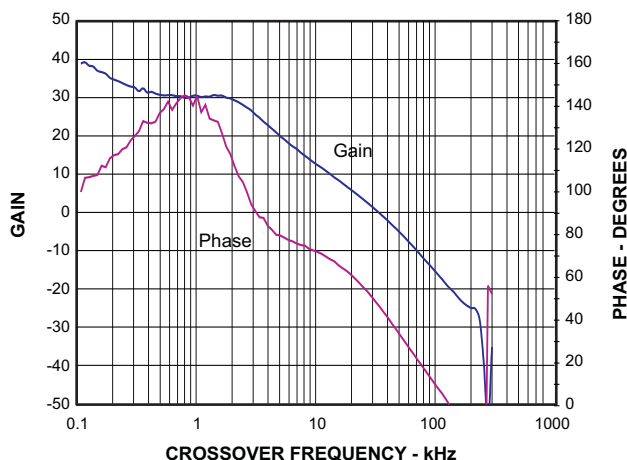


Figure 43. Overall System Gain and Phase Response

Figure 43 also shows the phase boost that gives the system a crossover phase margin of 47°.

The bill of materials for this application is shown below. The efficiency and load regulation from boards built from this design are shown in the following two figures. Gerber PC layout files and additional application information are available from the factory.

**Table 3. List of Materials, Buck Regulator, 12 V to 3.3 V and 5.0 V**

Ref. Des.	Value	Description	Size	Mfr.	Part Number
C1	100 $\mu$ F	Capacitor, Aluminum, SM, 25-V, 0.3 $\Omega$	8 x 10 mm	Sanyo	20SVP100M
C12	220 $\mu$ F	Capacitor, Aluminum, SM, 6.3-V, 0.4 $\Omega$	8 x 6.2 mm	Panasonic	EEVFC0J221P
C13	100 pF	Capacitor, Ceramic, 50V, [COG], [20%]	603	muRata	Std.
C3	0.1 pF	Capacitor, Ceramic, 50V, [X7R], [20%]	603	muRata	Std.
C2, C11	1 $\mu$ F	Capacitor, Ceramic, 50V, [X7R], [20%]	603	muRata	Std.
C4, C5	470 pF	Capacitor, Ceramic, 50V, [X7R], [20%]	603	muRata	Std.
C6	0.047 $\mu$ F	Capacitor, Ceramic, 50V, [X7R], [20%]	603	muRata	Std.
C7	10 pF	Capacitor, Ceramic, 50V, [COG], [20%]	603	muRata	Std.
C8	1500 pF	Capacitor, Ceramic, 50V, [X7R], [20%]	603	muRata	Std.
D1	12 V	Diode, Zener, 12-V, 350-mW	SOT23	Diodes, Inc.	BZX84C12T
D2		Diode, Schottky, 30-A, 30-V	SMC	On Semi	MBRS330T3
D3	12 V	Diode Zener 12-V 5 mA	VMD2	Rohm	VDZT2R12B
J1,J3		Terminal Block 4-Pin 15-A 5.1-mm	0.8 x 0.35	OST	ED2227
J2		Header, 2-pin, 100-mil spacing, (36-pin strip)	0.100 x 2	Sullins	PTC36SAAN
L1	33 $\mu$ H	Inductor, SMT, 3.2 A, .039 $\Omega$	12.5 x 12.5 mm	TDK	SLF12575T330M3R2PF
PCB		2 Layer PCB 2 Ounce Cu	1.4 x 2.12 x 0.062		HPA164
Q1		Trans, N-Chan Enhancement Switching, 50 mA	SOT-143B	Phillips	BSS83
Q2		MOSFET, P-ch, 30-V, 3.6-A, 75-m $\Omega$	SuperSOT-6	Fairchild	FDC654P
U1		IC, Low Cost Non-Sync Buck Controller	SO-8	TI	TPS40200D
R1	10 $\Omega$	Resistor, Chip, 1/16 W, 1%	603	Std.	Std.
R10	100 k $\Omega$	Resistor, Chip, , 1/16W, 1%	603	Std.	Std.
R11	10 k $\Omega$	Resistor, Chip, 1/16 W, 1%	603	Std.	Std.
R12	1 M $\Omega$	Resistor, Chip, 1/16 W, 1%	603	Std.	Std.
R13	49.9 $\Omega$	Resistor, Chip, 1/16 W, 1%	603	Std.	Std.
R2	0.02 $\Omega$	Resistor, Chip, W, 5%	2010	Std.	Std.
R3	68.1 k $\Omega$	Resistor, Chip, 1/16 W, 1%	603	Std.	Std.
R4	2.0 k $\Omega$	Resistor, Chip, 1/16 W, 1%	603	Std.	Std.
R5	0 $\Omega$	Resistor, Chip, 1/16 W, 1%	603	Std.	Std.
R6	26.7 k $\Omega$	Resistor, Chip, 1/16 W, 1%	603	Std.	Std.
R7	1.0 k $\Omega$	Resistor, Chip, 1/16 W, 1%	603	Std.	Std.
R8	300 k $\Omega$	Resistor, Chip, 1/16 W, 1%	603	Std.	Std.

## PC Board Plots

The following figures [Figure 44](#) through [Figure 46](#) show the design of the TPS40200EVM-001 printed circuit board. The design uses 2-layer, 2oz copper and is 1.4" x 2.3" in size. All components are mounted on the top side to allow the user to easily view, probe, and evaluate the TPS40200 control IC in a practical application. Moving components to both sides of the PCB or using additional internal layers can offer additional size reduction for space constrained applications.

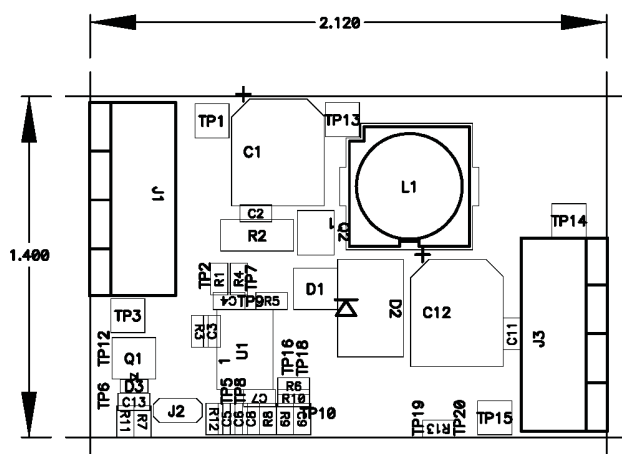


Figure 44. TPS40200EVM-001 Component Placement (Viewed from Top)

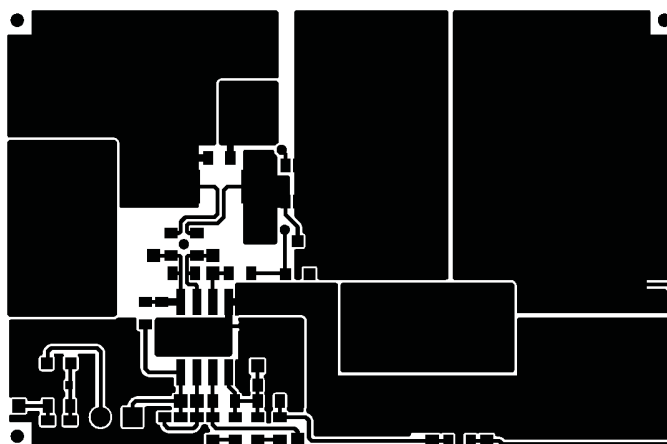


Figure 45. TPS40200EVM001 Top Copper (Viewed from Top)



Figure 46. TPS40200EVM-001 Bottom Copper (X-Ray View from Top)

## Application 2: 18 - 50 V Input, 16 V at 1 A Output

This is an example of using the TPS40200 in a higher voltage application. The output voltage is 16 V at 1 A with an 18 to 50 V input. Module boards built to this schematic and a test report are available from the factory. Some of the test results are shown below.

### Test Results

The following two curves demonstrate some of the performance obtained from this application. Further information and support material is available from the factory.

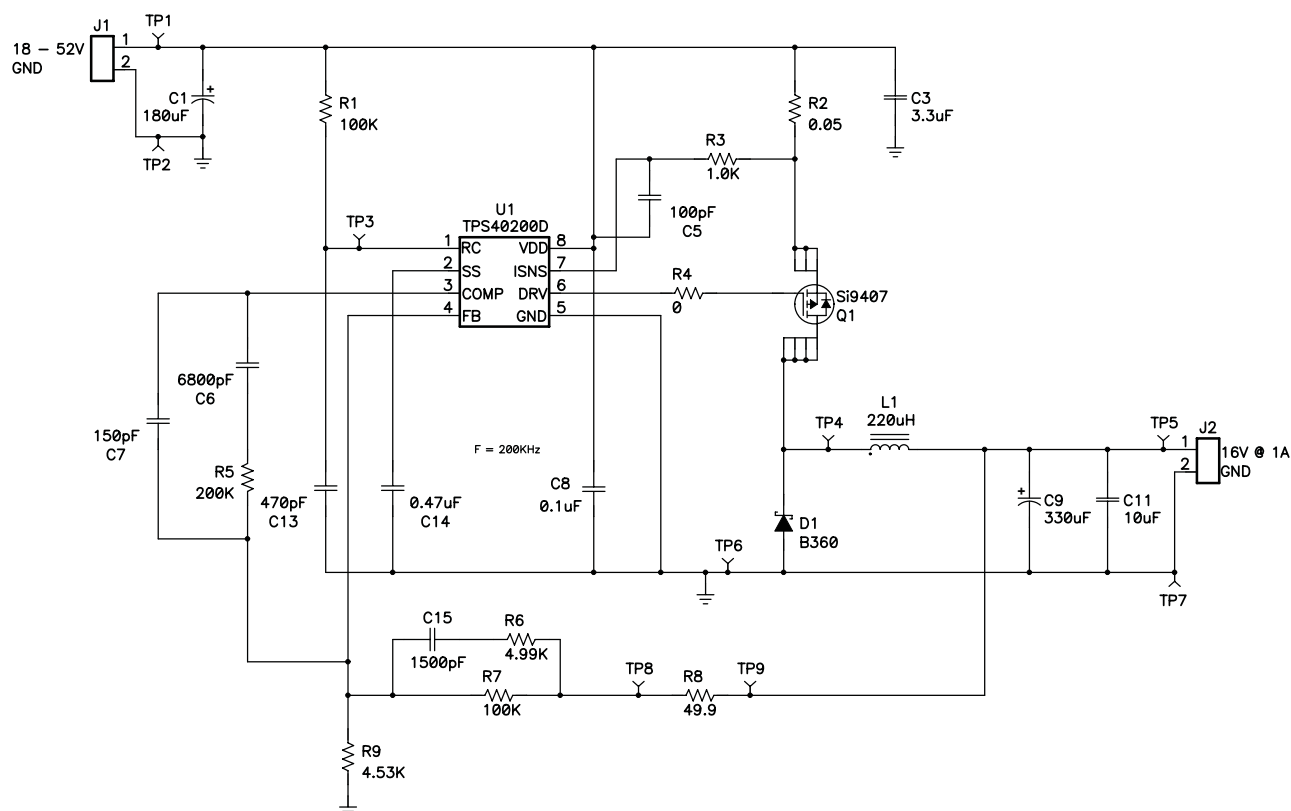


Figure 47. Buck Converter.  $V_{IN} = 18 - 50$ ;  $V_{OUT} = 16\text{ V @ }1\text{ A}$

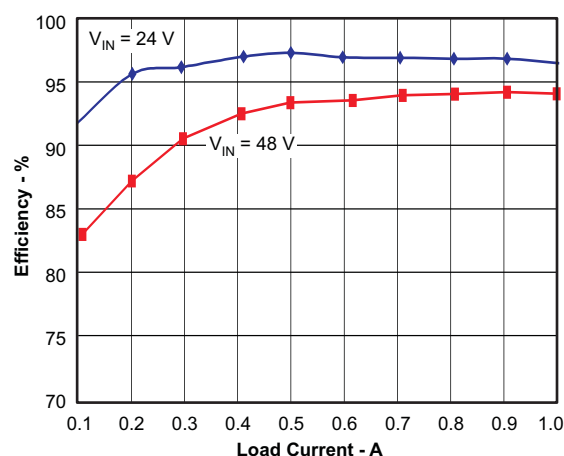


Figure 48. Efficiency vs. Load

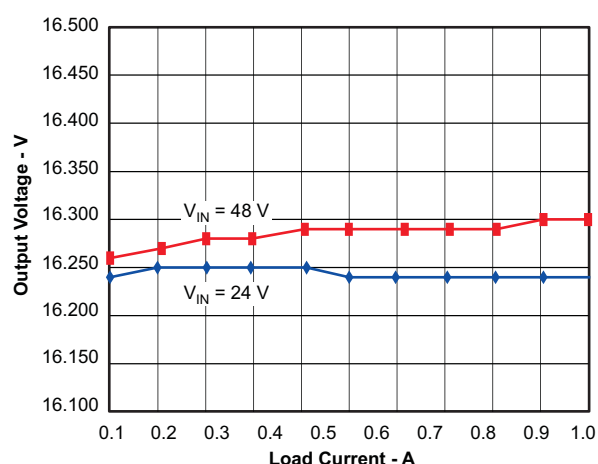


Figure 49. Load Regulation, Two Input Voltage Extremes

### Application 3: Wide Input Voltage LED Constant Current Driver

This application uses the TPS40200 as a buck controller that drives a string of LED diodes. The feedback point for this circuit is a sense resistor in series with this string. The low 0.7-V reference minimizes power wasted in this resistor, and maintains the LED current at a value given by  $0.7/R_{\text{SENSE}}$ . As the input voltage is varied, the duty cycle changes to maintain the LED current at a constant value so that the light intensity does not change with large input voltage variations.

Vin 12V – 30V

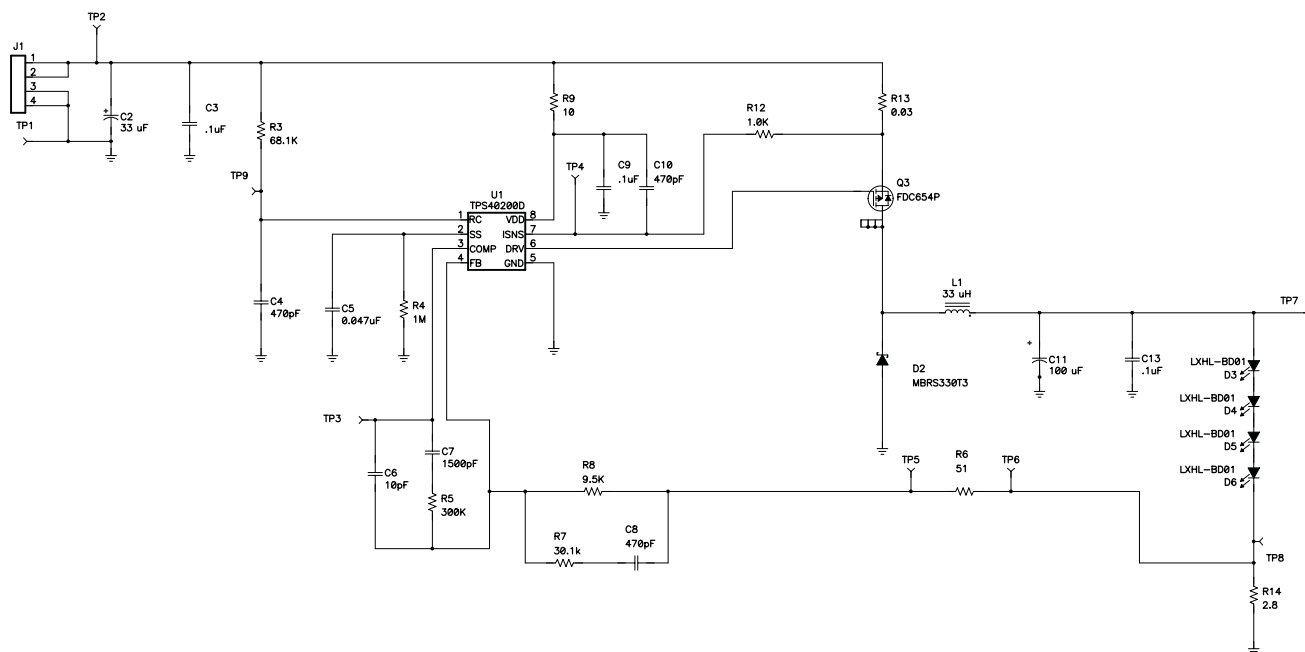


Figure 50. Wide Input Voltage Range LED Driver

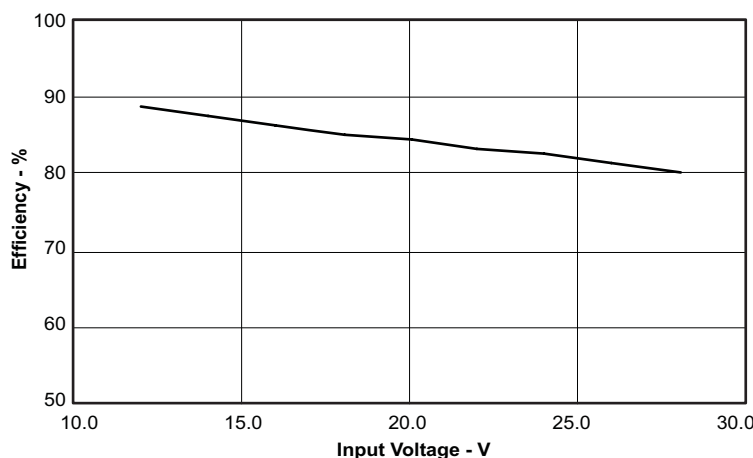
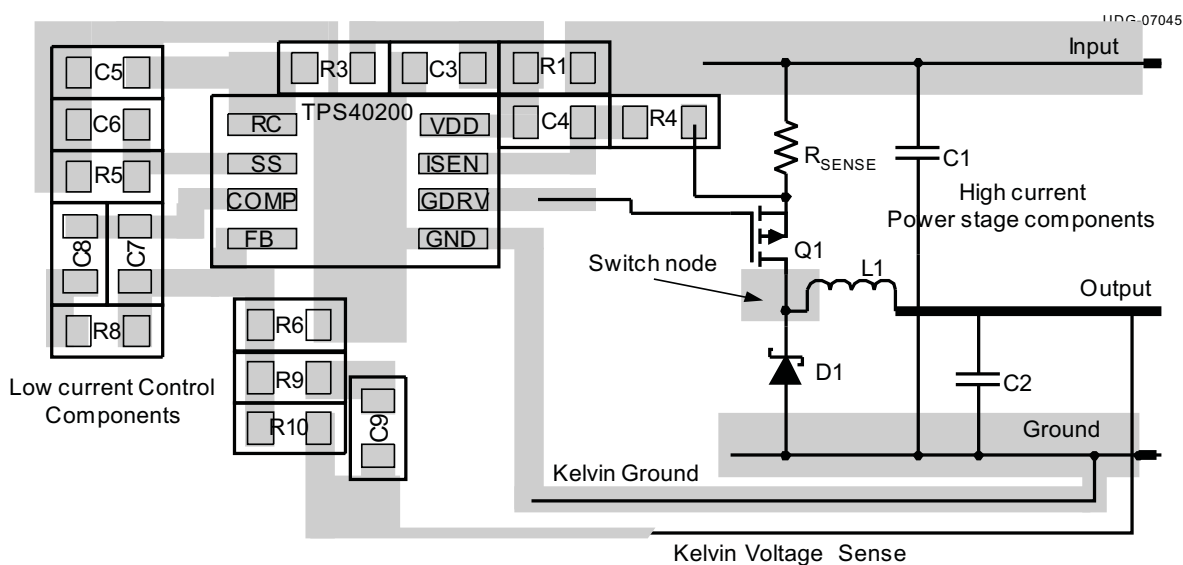
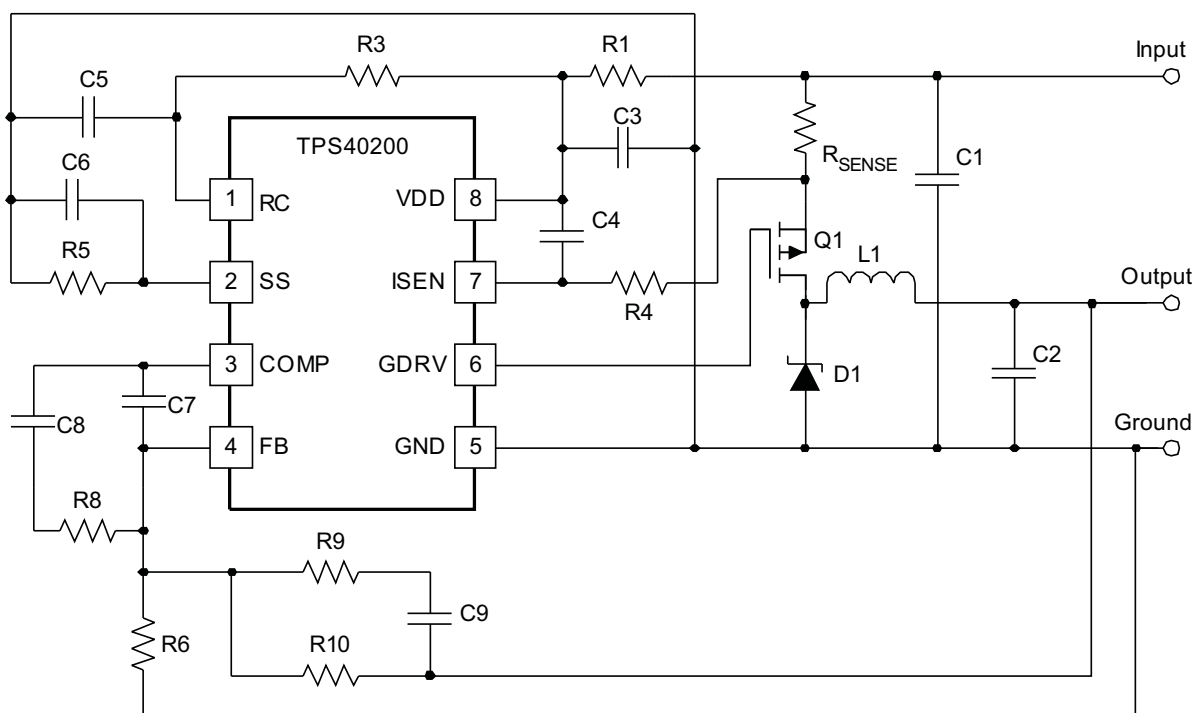


Figure 51. Efficiency vs Input Voltage



## DESIGN REFERENCES

## PC BOARD LAYOUT RECOMMENDATIONS

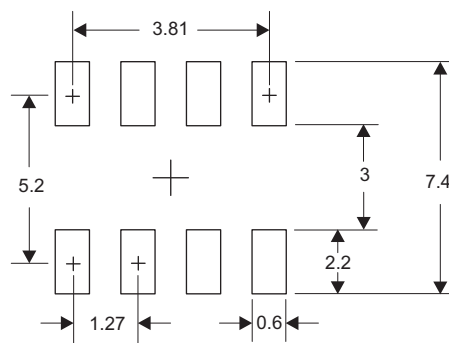


### Figure 52. PC Board Layout Recommendations

## Layout Hints

- AC current loops must be kept as short as possible. For the maximum effectiveness from C3, place it near the VDD pin of the controller and design the input AC loop consisting of C1-R<sub>SENSE</sub>-Q1-D1 to be as short as possible. Excessive high frequency noise on VDD during switching degrades overall regulation as the load increases.
- The output loop A (D1-L1-C2) should also be kept as small as possible. Otherwise, the application's output noise performance will be degraded.
- It is recommended that traces carrying large AC currents NOT be connected through a ground plane. Instead, use PCB traces on the top layer to conduct the AC current and use the ground plane as a noise shield. Split the ground plane as necessary to keep noise away from the TPS40200 and noise sensitive areas such as feedback resistors R6, and R10.
- Keep the SW node as physically small as possible to minimize parasitic capacitance and to minimize radiated emissions
- For good output voltage regulation, Kelvin connections should be brought from the load to R6 and R10.
- The trace from the R6-R10 junction to the TPS40200 should be short and kept away from any noise source, such as the SW node.
- The Gate drive trace should be as close to the power FET's Gate as possible.

The TPS40200 is encapsulated in a standard Plastic SOIC-8 package. The typical PC-board layout for this package is shown in [Figure 53](#).



Dimensions are in millimeters

**Figure 53. Suggested SOIC-8 PC-Board Footprint**

## Related Parts

- TPS4007/9 Low Input Synchronous Buck Controller
- TL5001 Wide Input Range Controller

## Reference Documents

- *Under the hood of low voltage DC/DC converters* – SEM1500 Topic 5 –2002 Seminar Series
- *Understanding Buck Power Stages in Switchmode Power Supplies* – SLVA057 - March 1999
- *Design and Application Guide for High Speed MOSFET Gate Drive Circuits*- SEM 1400 – 2001 Seminar Series
- *Designing Stable Control Loops* - SEM 1400 – 2001 Seminar Series
- Power.TI.com

## PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TPS40200D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS40200DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS40200DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS40200DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

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**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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**TAPE AND REEL INFORMATION**



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS40200DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

## TAPE AND REEL BOX DIMENSIONS

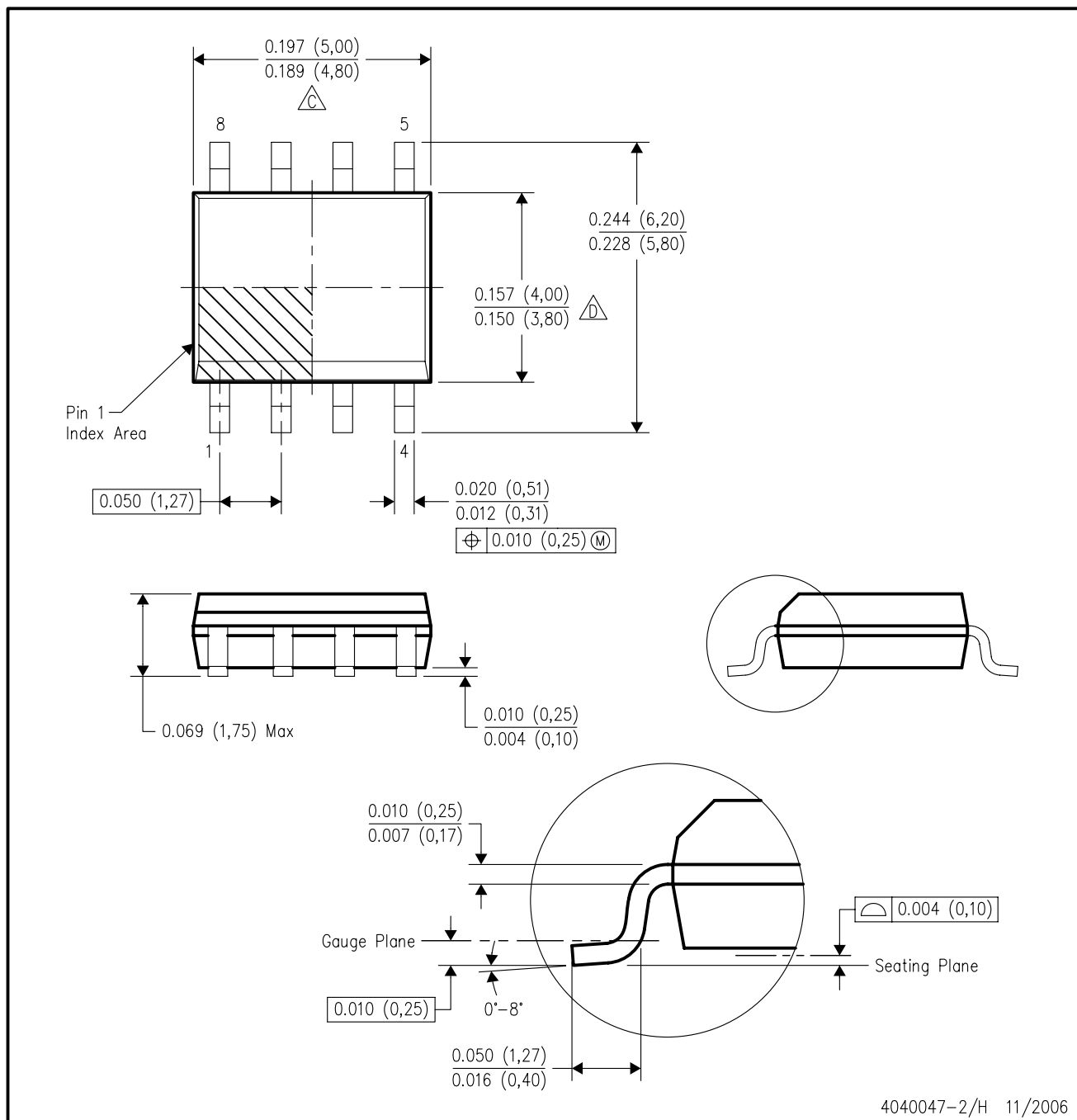


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS40200DR	SOIC	D	8	2500	340.5	338.1	20.6

## D (R-PDSO-G8)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).  
B. This drawing is subject to change without notice.  
C Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.  
D Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.  
E. Reference JEDEC MS-012 variation AA.

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